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Kim

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(54) **LIQUID CRYSTAL DISPLAY**

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(21) Appl. No.: **12/878,623**

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Primary Examiner — Kimnhung Nguyen

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(57) **ABSTRACT**

Related U.S. Application Data

(63) Continuation of application No. 11/403,121, filed on Apr. 12, 2006, now Pat. No. 7,796,104.

A liquid crystal display includes an array of pixels. Each pixel is divided into a first sub-pixel and a second sub-pixel, and different data voltages are separately applied to (or evolved at) the two sub-pixels, thereby enhancing the lateral side visibility. Each sub-pixel includes a sub-pixel electrode (connected to the drain electrode of a sub-pixel's switching element) overlapped with the sub-pixel's storage electrode. A first predetermined voltage is applied to the first sub-pixel and second predetermined voltage is applied the second sub-pixel, and thus the first sub-pixel electrode may receive a voltage lower than the voltage of the second sub-pixel electrode. The first sub-pixel electrode may be larger in area than the second sub-pixel electrode. The overlapping area between the first drain electrode and the storage electrode of a first sub-pixel may be larger than the overlapping area between the drain electrode and the storage electrode of a second sub-pixel. Thus the kickback voltage of the first sub-pixel may be substantially the same as the kickback voltage of the second sub-pixel.

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G09G 3/36 (2006.01)

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(58) **Field of Classification Search** 345/87–100, 345/204; 257/59; 349/38–43, 54, 73, 74, 349/141–147, 187

See application file for complete search history.

9 Claims, 15 Drawing Sheets

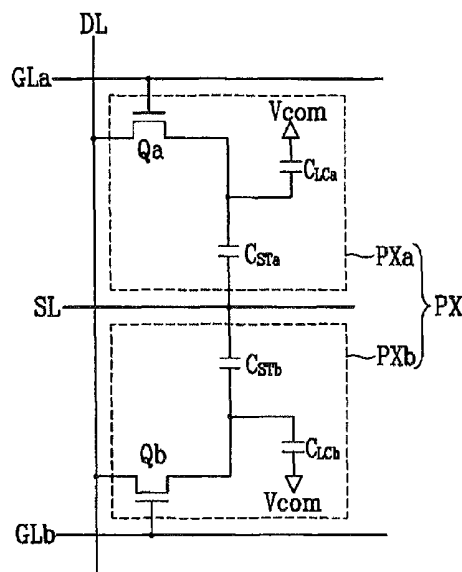


FIG. 1A

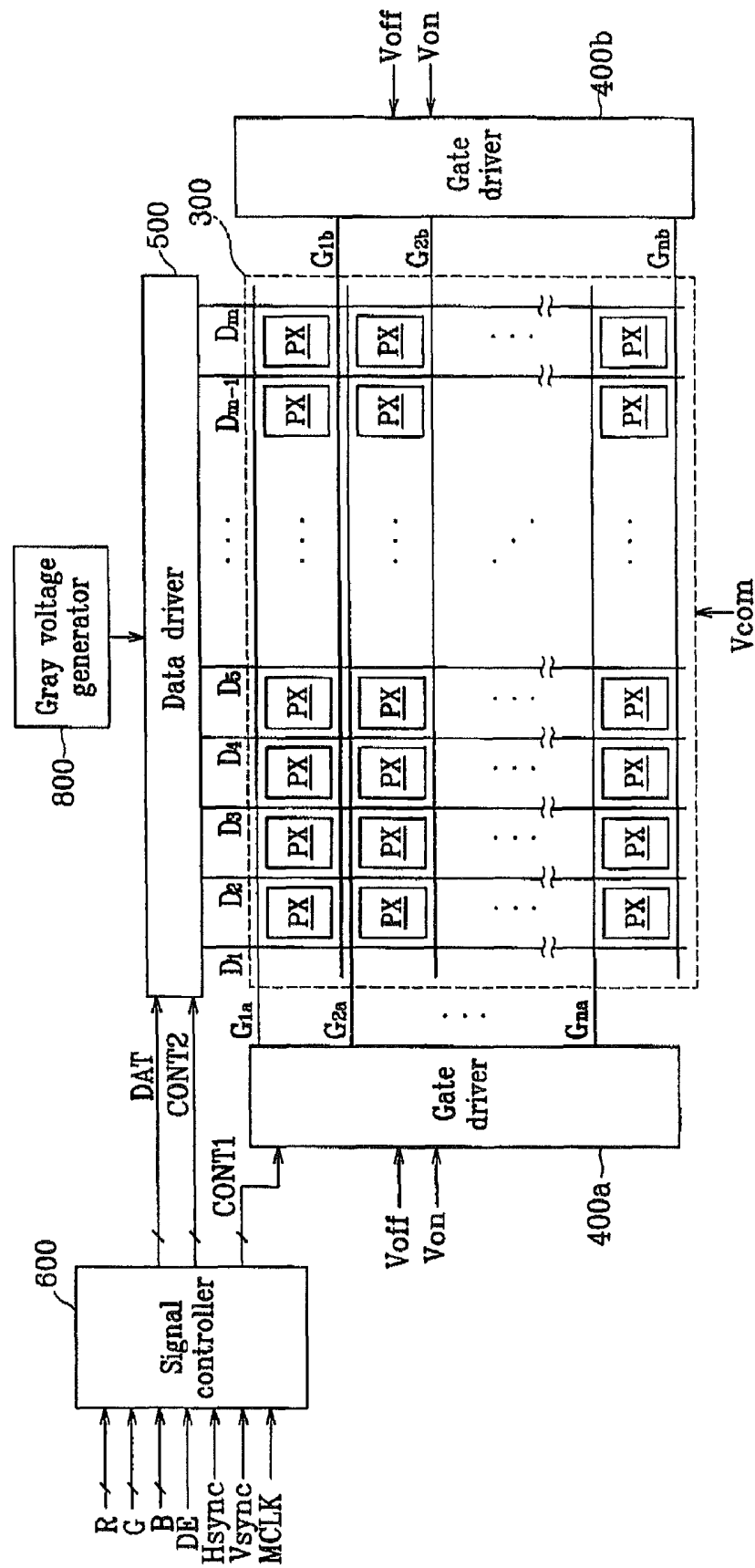


FIG. 1B

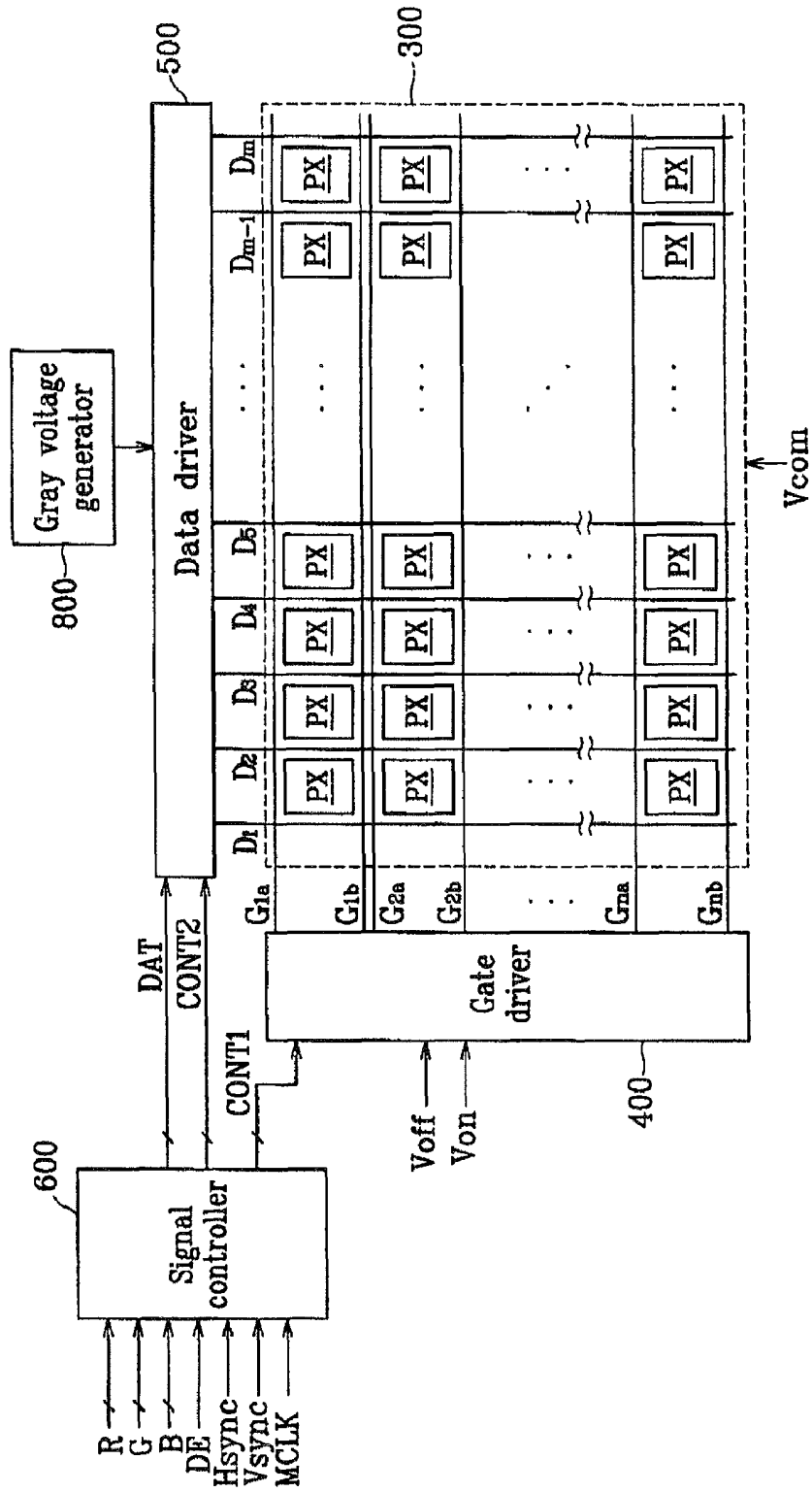


FIG. 1C

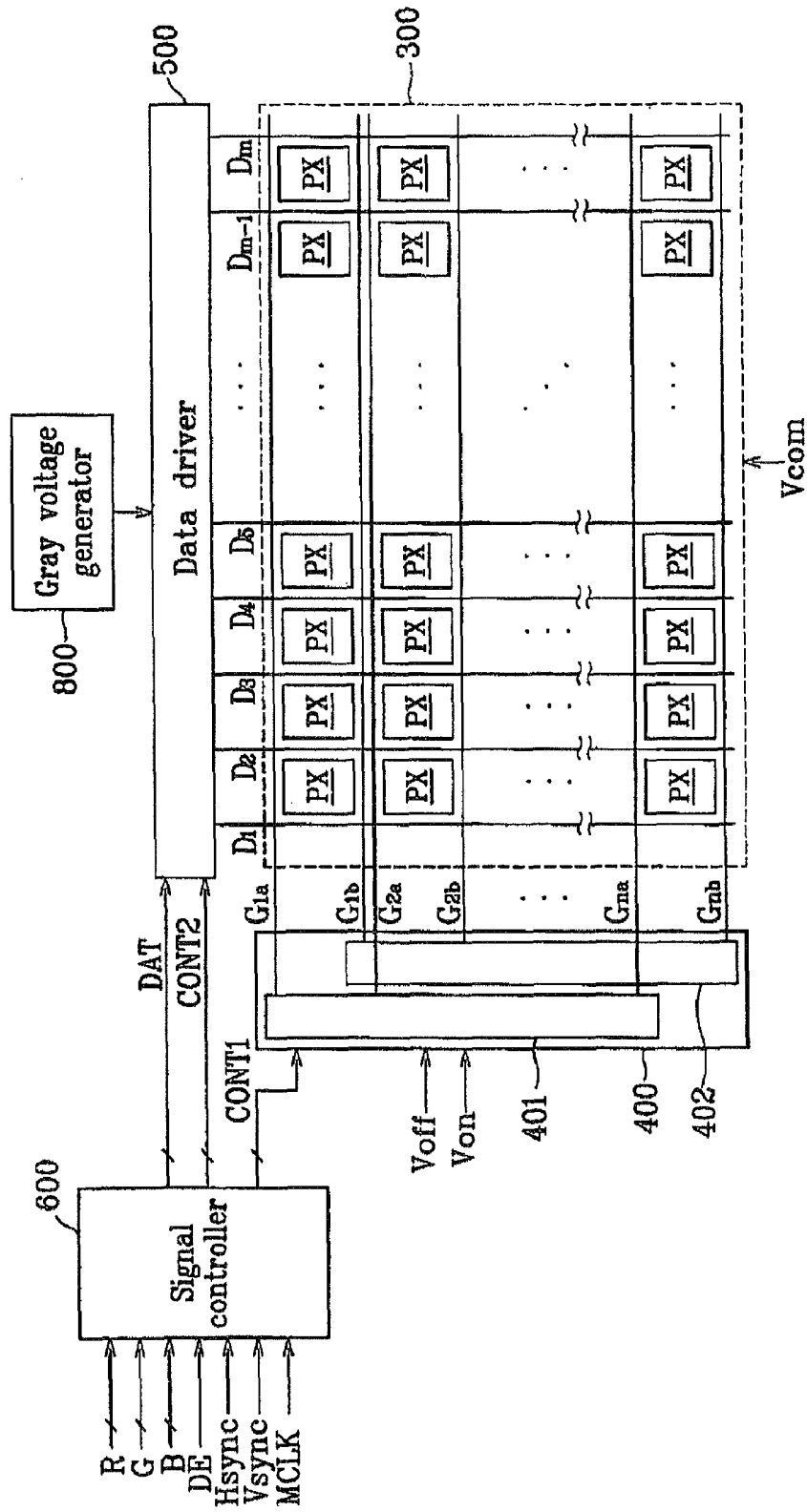


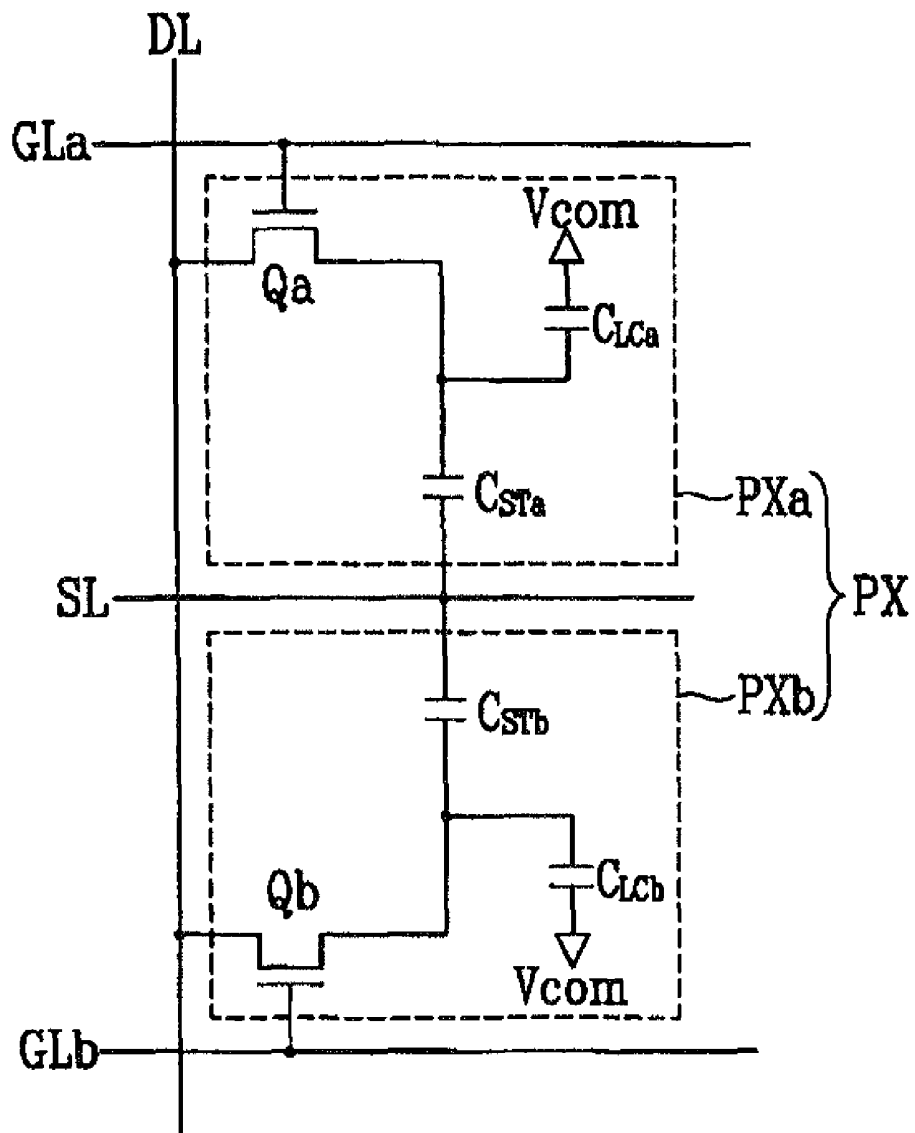
FIG. 2

FIG. 3

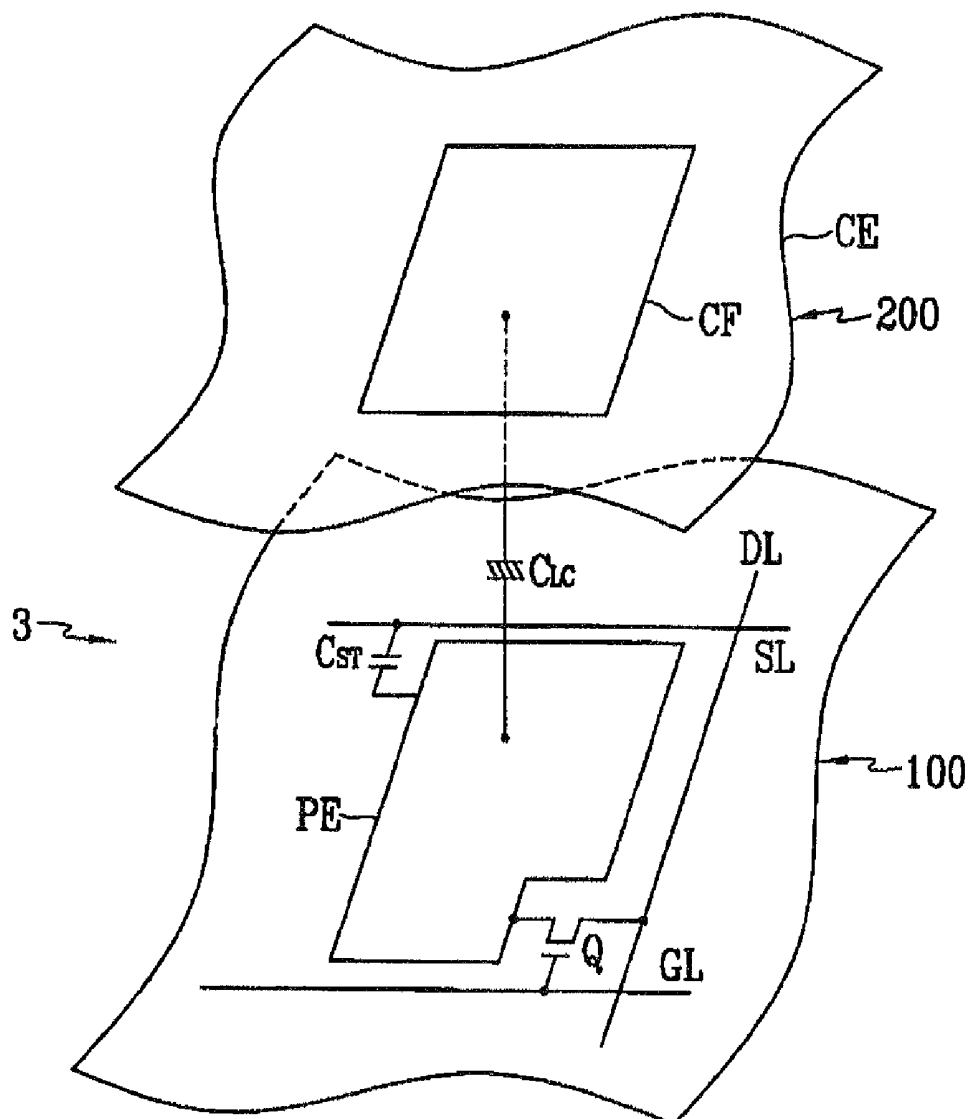


FIG. 4

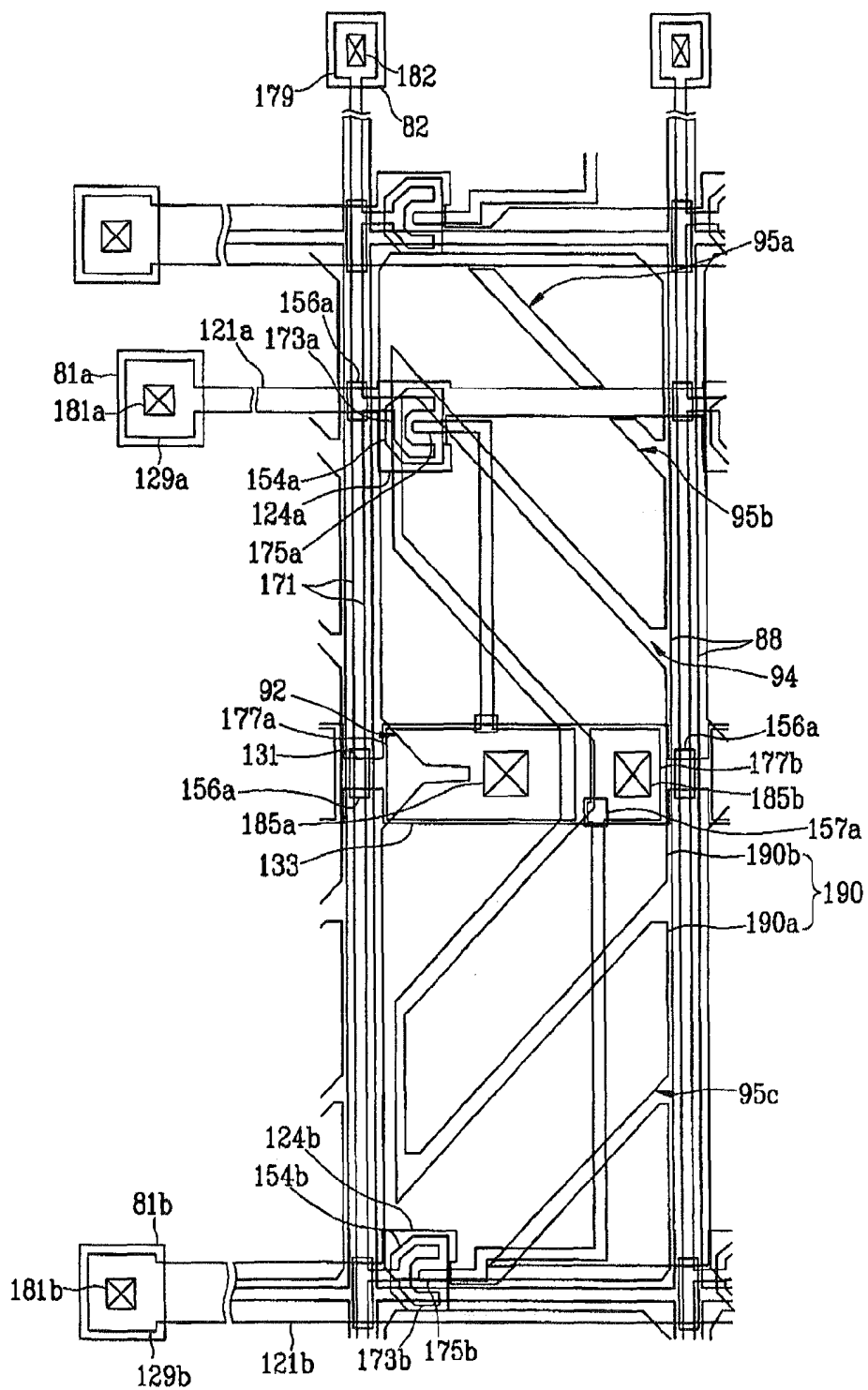


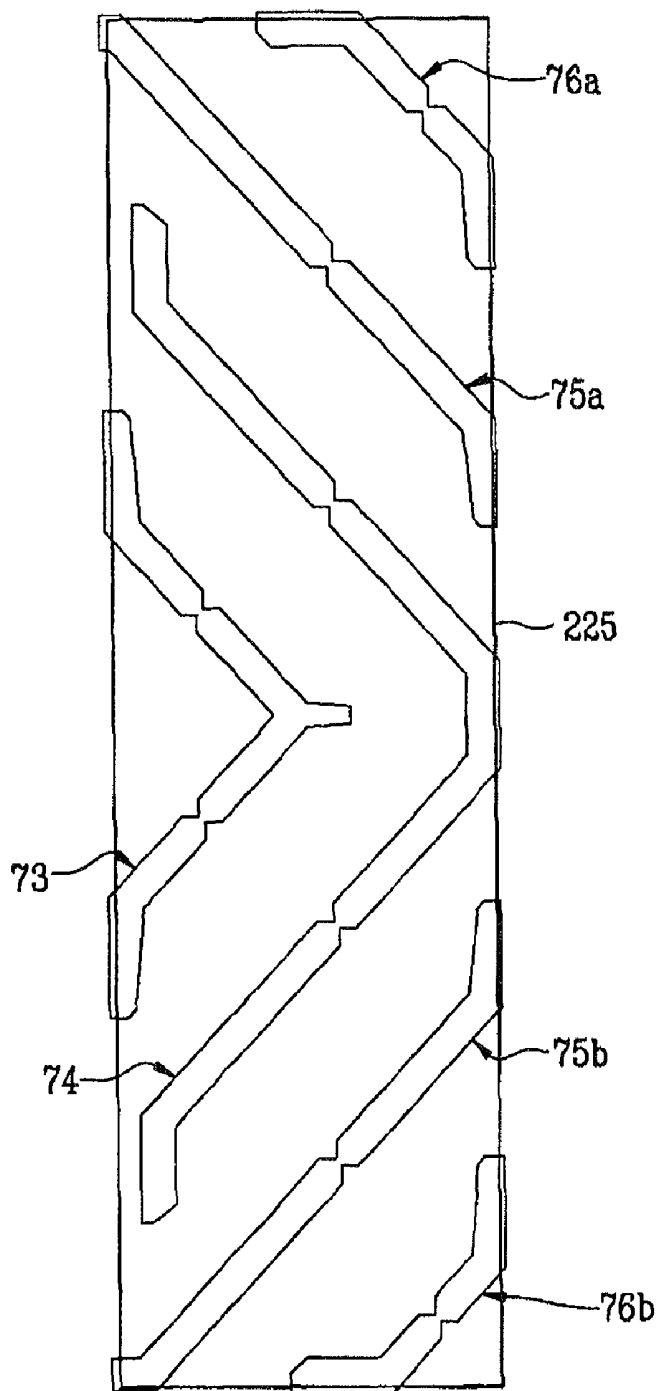
FIG. 5

FIG. 6

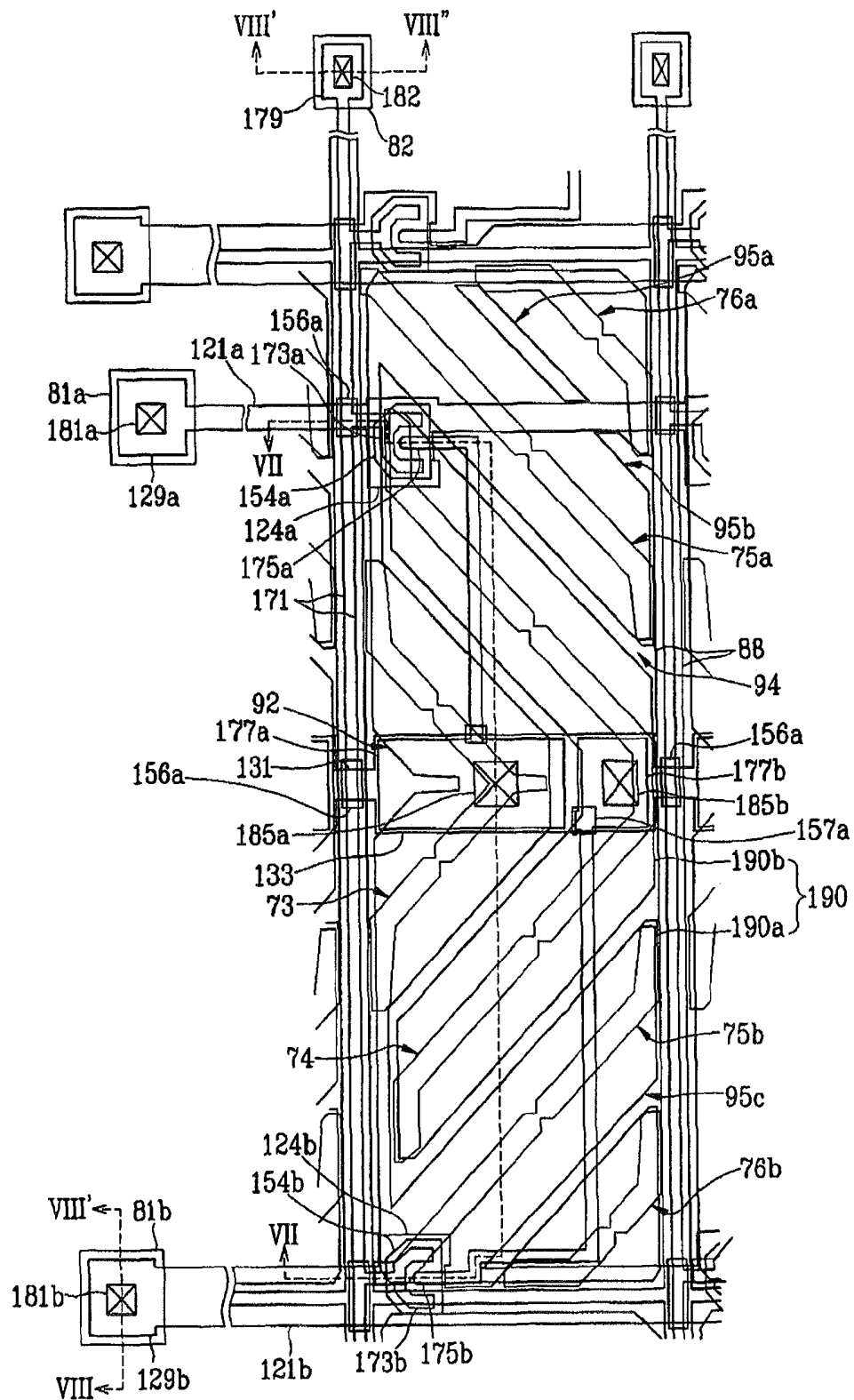


FIG. 7

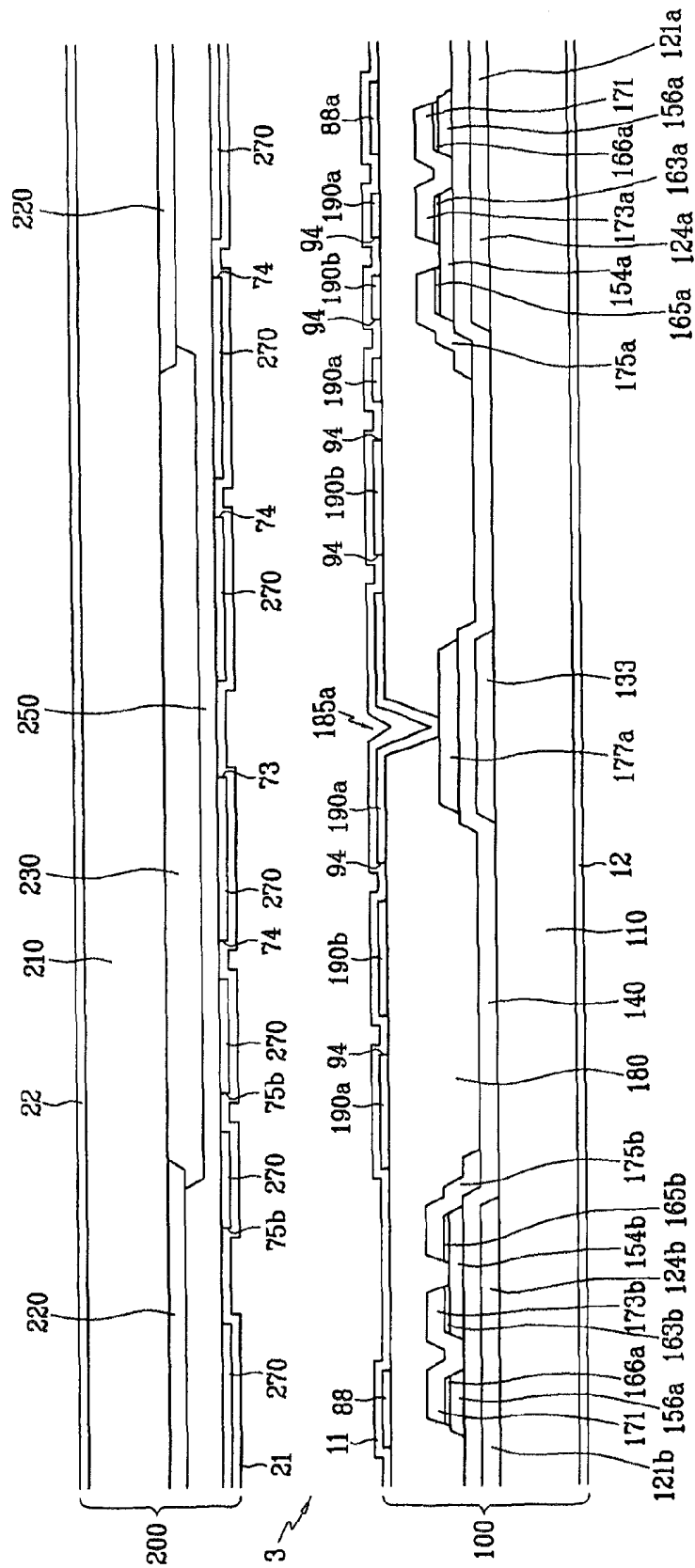


FIG. 8

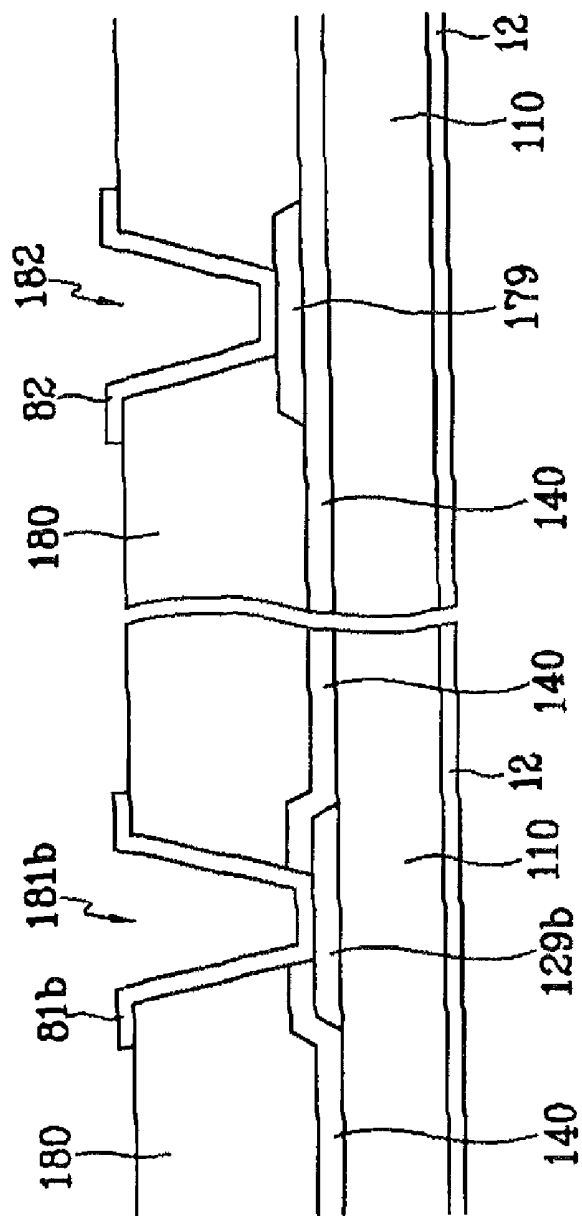


FIG. 9

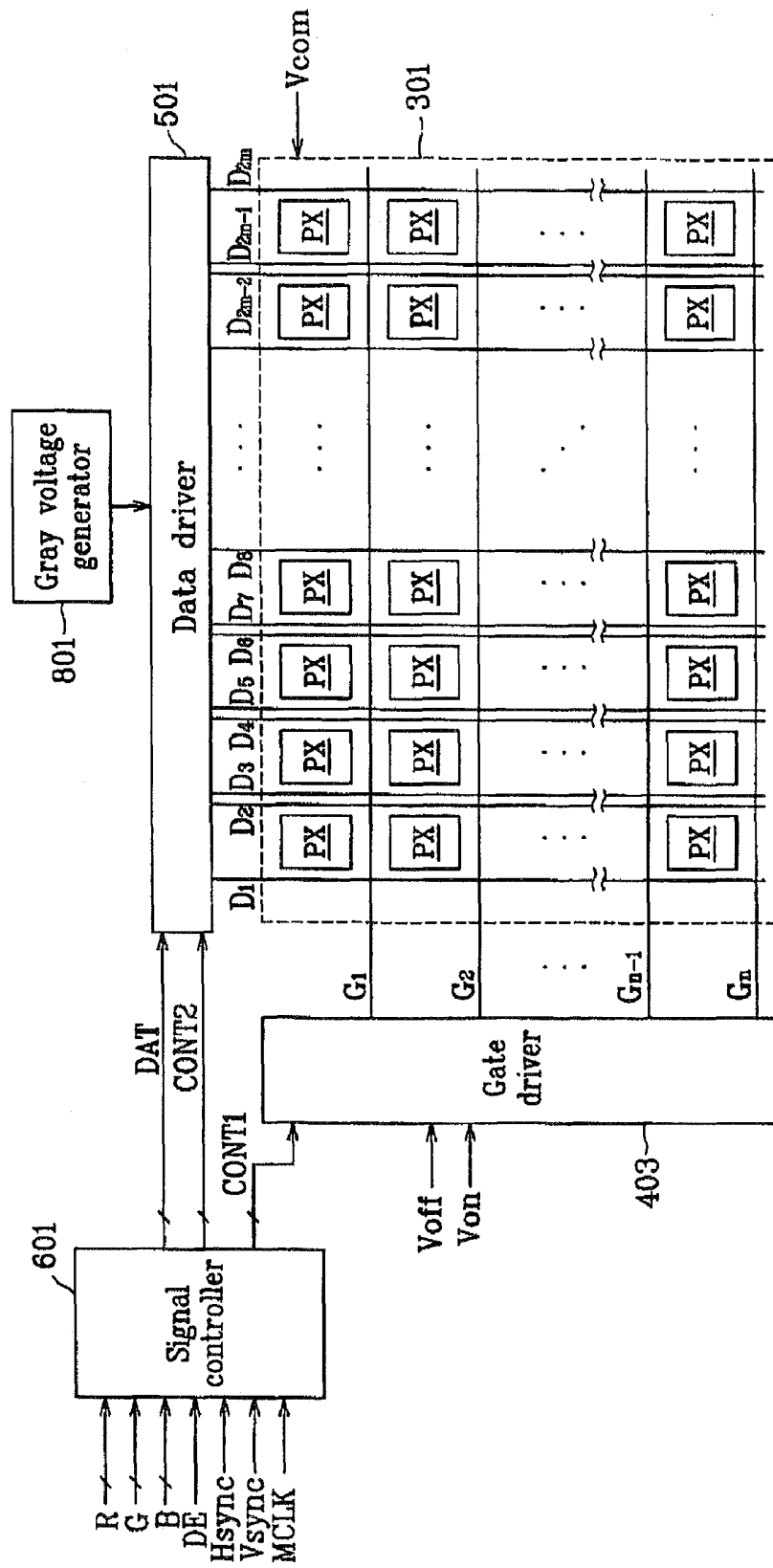


FIG. 10

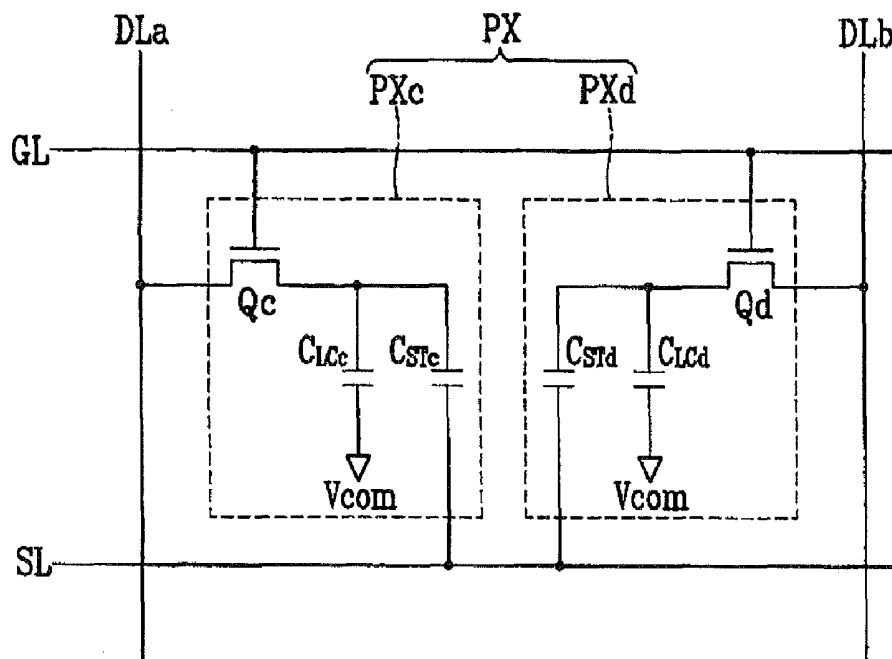


FIG. 11

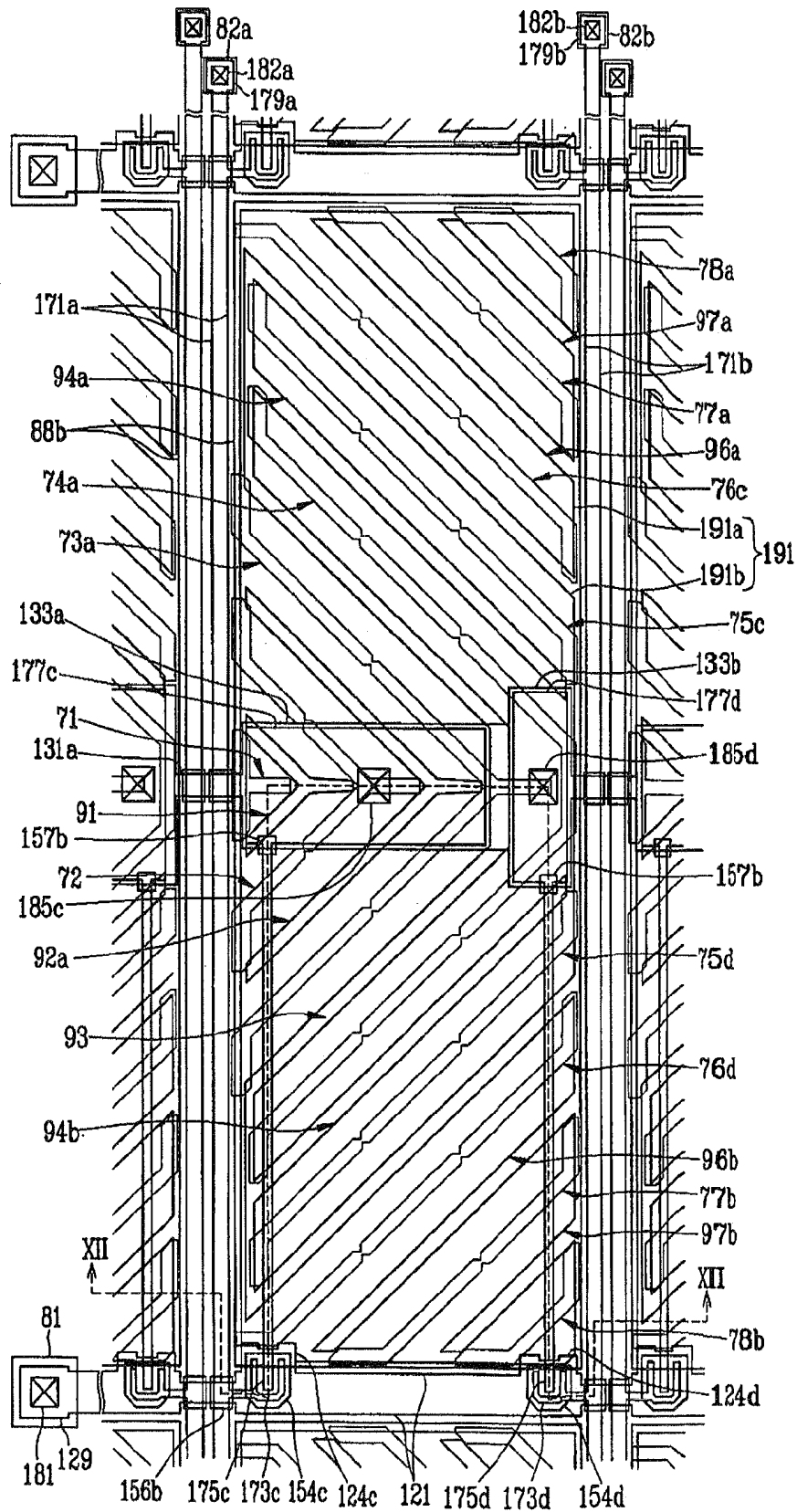


FIG. 12

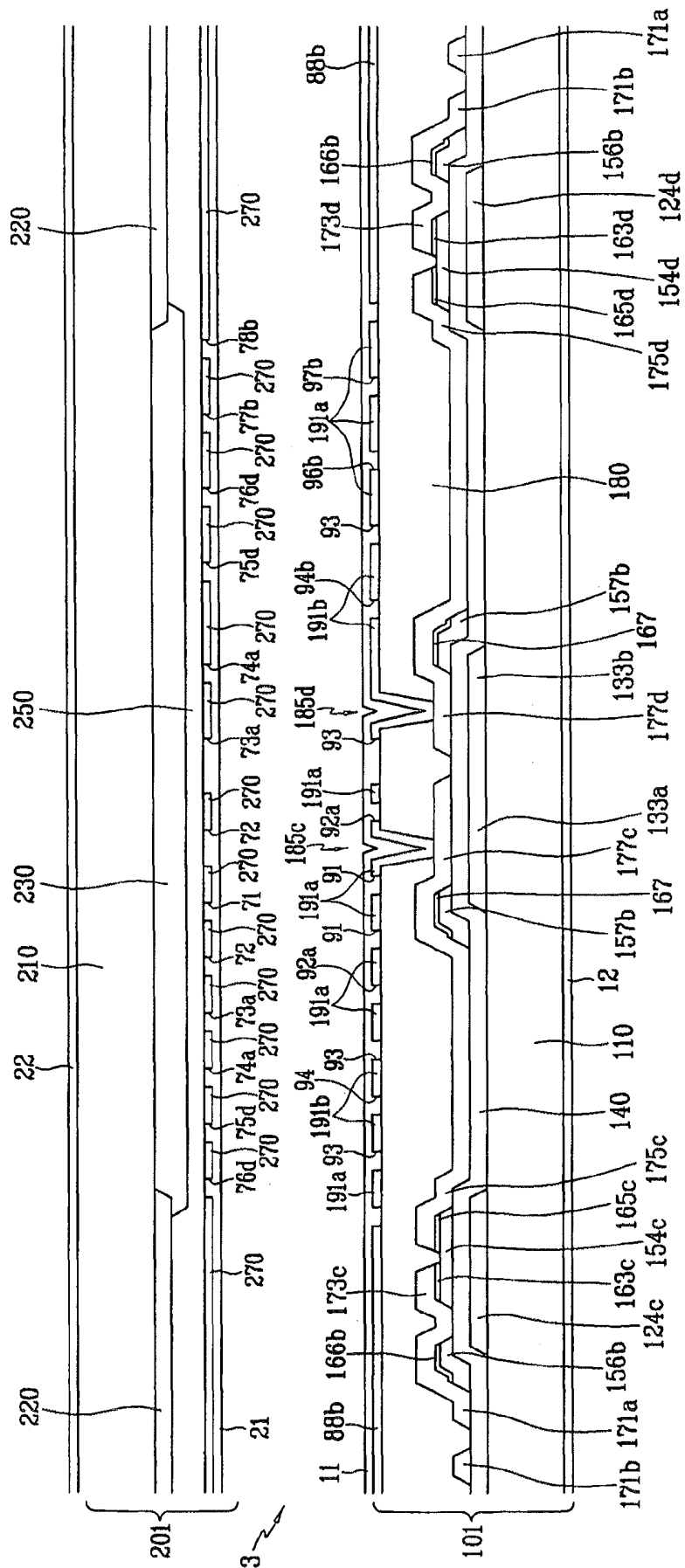
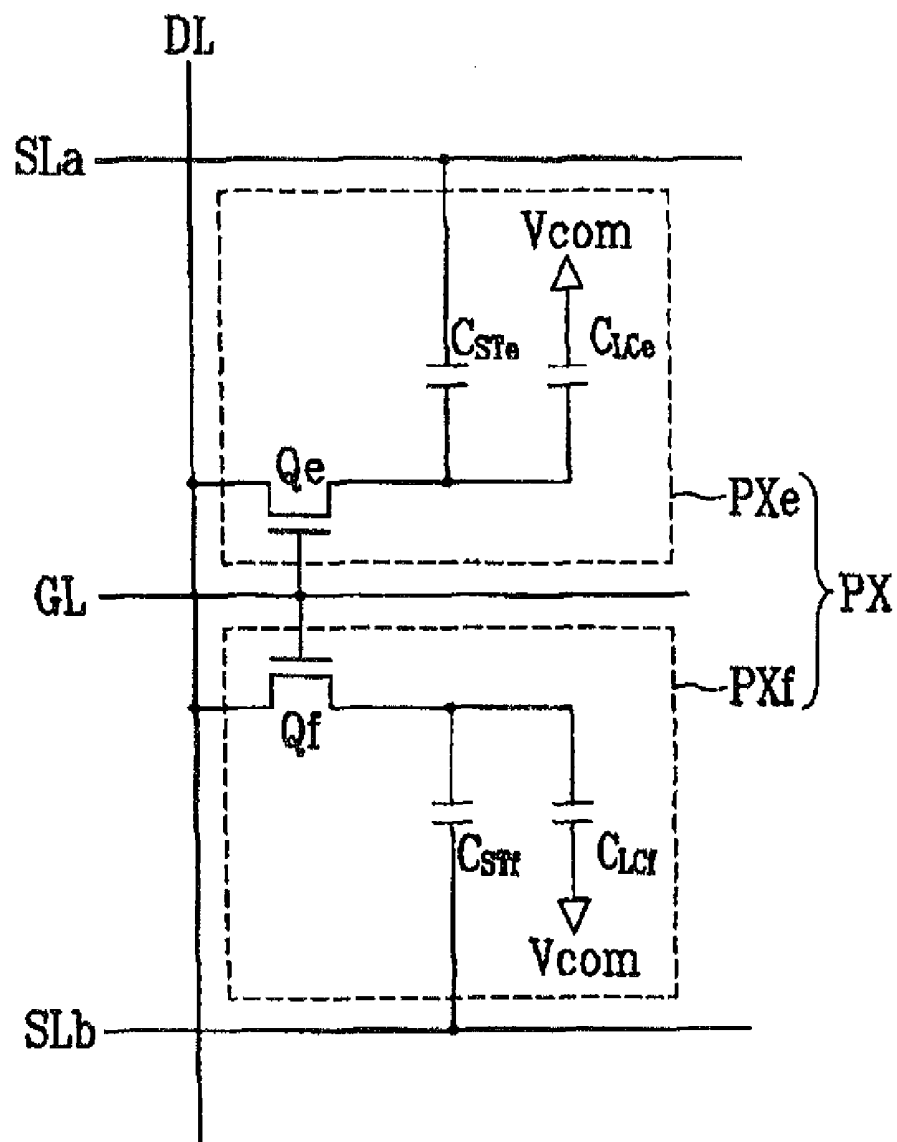


FIG. 13

LIQUID CRYSTAL DISPLAY

RELATED APPLICATION

This application is a Continuation Application of U.S. patent application Ser. No. 11/403,121, filed Apr. 12, 2006, now U.S. Pat. No. 7,796,104 which claims priority under 35 U.S.C. §119 of Korean Patent Application No. 10-2005-0030678 filed on Apr. 13, 2005, the contents of which are incorporated by reference herein in their entirety.

BACKGROUND OF THE INVENTION

(1) Field of the Invention

The present invention relates to a liquid crystal display.

(2) Description of the Related Art

A liquid crystal display ("LCD"), one of the most extensively used flat panel display devices, typically includes two substrates having field-generating electrodes (such as pixel and common electrodes) mounted thereon, and a liquid crystal layer sandwiched between the substrates. The LCD generates an electric field in the liquid crystal layer by applying voltages to the field-generating electrodes, and aligns the liquid crystal molecules of the liquid crystal layer to control the polarization of light incident thereto (e.g., from a "back-light"), thereby displaying the desired images.

In a vertically aligned ("VA") mode LCD, the directions of liquid crystal molecules are aligned vertical to the upper and lower panels (substrates) while no electric field is applied, and gives a high contrast ratio and a wide reference viewing angle. The reference viewing angle refers to a viewing angle with a contrast ratio of 1:10, or an inter-gray luminance inversion limit angle.

In the VA mode LCD, cutouts or protrusions may be formed at the field-generating electrodes to realize a wide viewing angle. As the direction of the liquid crystal molecules to be inclined is determined by the cutouts or protrusions, the inclination directions of the liquid crystal molecules can be diversified, thereby widening the reference viewing angle.

However, the VA mode LCD provides poor visibility at the lateral sides thereof, as compared to the visibility at the front side thereof. For example, in a patterned vertically aligned (PVA) mode LCD having cutouts, the luminance thereof is heightened as it comes to the lateral side thereof, and in a serious case, the luminance difference between the high grays is eliminated so that the display image may appear to be distorted.

In order to enhance the lateral side visibility, it has been proposed that a pixel controlled by one data (e.g., one color pixel) should be divided into two sub-pixels, which are capacitor-combined with each other. A voltage is directly applied to one of the sub-pixels, and a voltage drop is caused at the other sub-pixel due to the capacitor combination. In this way, the two sub-pixels are differentiated in voltage from each other and have different light transmittances.

However, with such a method, the transmittances of the two sub-pixels cannot be directly and correctly controlled to the desired level, and in particular, the light transmittance is differentiated for the respective color. The voltages cannot be differently adjusted with respect to the respective colors. Furthermore, the aperture ratio is deteriorated due to the addition of a conductor for a capacitor combination, and the light transmittance is reduced due to the capacitor combination-induced voltage drop.

SUMMARY OF THE INVENTION

A liquid crystal display includes an array of pixels. Each pixel is divided into a first sub-pixel and a second sub-pixel,

and different data voltages may be separately applied to the two sub-pixels, thereby enhancing the lateral side visibility. Each sub-pixel includes a sub-pixel electrode (connected to the drain electrode of a sub-pixel's switching element) overlapped with the sub-pixel's storage electrode. The first sub-pixel electrode may be larger in area than the second sub-pixel electrode. A first predetermined voltage may be applied to the first sub-pixel and second predetermined voltage may be applied to the second sub-pixel, and thus the first sub-pixel electrode may receive a voltage lower than the voltage of the second sub-pixel electrode. The overlapping area between the first drain electrode and the storage electrode of a first sub-pixel may be larger than the overlapping area between the drain electrode and the storage electrode of a second sub-pixel. Thus the kickback voltage of the first sub-pixel may be substantially the same as the kickback voltage of the second sub-pixel.

Embodiments of the present invention provide a liquid crystal display having enhanced lateral side visibility with reasonable light transmittance and aperture ratio.

According to one aspect of the present invention, a liquid crystal display includes a plurality (array) of pixel each pixel including: first and second sub-pixels. Each sub-pixel includes a switch (e.g., a thin film transistor (TFT) having drain, gate and source electrodes), a sub-pixel electrode (of an LC capacitor), and a storage electrode (of a storage capacitor). The drain electrodes overlap the storage electrodes. A predetermined voltage is applied to the second sub-pixel electrode, and the first sub-pixel electrode receives a voltage lower than the voltage of the second sub-pixel electrode. The first and second storage electrodes are electrically separated from each other. The overlapping area between the first drain electrode and the storage electrode is larger than the overlapping area between the second drain electrode and the storage electrode.

The data voltages applied to the first and second sub-pixel electrodes of each pixel may be different (in magnitude or timing) from each other, and they may be derived from one image information signal.

In some embodiments, first and second gate lines transmit (different) gate signals to the first and second gate electrodes, respectively, and data transmits (the same) data voltages to the first and second source electrodes.

The timing of the gate signals (voltages) applied to the first and second gate lines may be different from each other.

In other embodiments, a gate line transmits (the same) gate signals to first and second gate electrodes, while first and second data lines transmit (different) data voltages to the first and second source electrodes, respectively.

In other embodiments, a gate line transmits (the same) gate signals to first and second gate electrodes, and a data line transmits (the same) data voltages to first and second source electrodes.

The channel width to channel length ratio of the first thin film transistor (TFT) of the first sub-pixel may be different (e.g., greater) from the channel width to channel length ratio of the second thin film transistor (TFT) of the second sub-pixel.

The first sub-pixel electrode may be larger in area than the second sub-pixel electrode.

According to another aspect of the present invention, a liquid crystal display includes a plurality (array) of pixels, each pixel including a first sub-pixel and a second sub-pixel. A plurality of first gate lines connect to the first sub-pixels. A plurality of first data lines cross (perpendicular to) the first gate lines, and are connected to the first sub-pixels. The second sub-pixel is connected to either one or both of (e.g., at

least one of) the first gate line and the first data line. A predetermined voltage is applied to the first sub-pixel, and the voltage received by the second sub-pixel may be higher than the voltage received by the first sub-pixel. The kickback voltage of the first sub-pixel may substantially the same as the kickback voltage of the second sub-pixel.

In some embodiments, a plurality of second gate lines may be connected to the second sub-pixels, while the second sub-pixels are be connected to the first data lines. Thus, the first sub-pixel may include a first switching element connected to the first gate line and the first data line, a first liquid crystal capacitor connected to the first switching element, and a first storage capacitor connected to the first switching element. The second sub-pixel may include a second switching element connected to the second gate line and the first data line, a second liquid crystal capacitor connected to the second switching element having a capacitance smaller than the capacitance of the first liquid crystal capacitor, and a second storage capacitor connected to the second switching element having a capacitance smaller than the capacitance of the first storage capacitor.

In other embodiments, a plurality of second data lines may be connected to the second sub-pixels, while the second sub-pixels may be connected to the first gate lines. Thus, the first sub-pixel may include a first switching element connected to the first gate line and to the first data line, a first liquid crystal capacitor connected to the first switching element, and a first storage capacitor connected to the first switching element. The second sub-pixel may include a second switching element connected to the first gate line and to the second data line, a second liquid crystal capacitor connected to the second switching element having a capacitance smaller than the capacitance of the first liquid crystal capacitor, and a second storage capacitor connected to the second switching element having a capacitance smaller than the capacitance of the first storage capacitor.

According to another aspect of the present invention, a liquid crystal display includes a plurality (array) of pixels arranged in the form of a matrix, each pixel including a first sub-pixel and a second sub-pixel. A plurality of first gate lines connect to the first sub-pixels. A plurality of first data lines cross (are perpendicular to) the first gate lines, and are connected to the first sub-pixels. The first sub-pixel includes a first switching element connected to the first gate line and to the first data line, a first liquid crystal capacitor connected to the first switching element, and a first storage capacitor connected to the first switching element. The second sub-pixel includes a second switching element connected to either one or both (at least one) of the first gate line and the first data line, a second liquid crystal capacitor connected to the second switching element having a capacitance smaller than the capacitance of the first liquid crystal capacitor, and a second storage capacitor connected to the second switching element having a capacitance smaller than the capacitance of the first storage capacitor. A predetermined voltage is applied to the second sub-pixel, and the first sub-pixel may receive voltage lower than the voltage received by the second sub-pixel.

A plurality of second gate lines may be connected to the second switching elements, while the second switching elements may be connected to the first data lines.

Alternatively, plurality of second data lines may be connected to the second switching elements, while the second switching elements may be connected to the first gate lines.

The present invention will be described more fully hereinafter with reference to the accompanying drawings, in which preferred embodiments of the invention are shown. The present invention may, however, be embodied in many differ-

ent forms and should not be construed as limited to the exemplary embodiments set forth herein.

In the drawings, the thickness of layers, films, and regions are exaggerated for clarity. Like numerals refer to like elements throughout. It will be understood that when an element such as a layer, film, region, or substrate is referred to as being "on" another element, it can be directly on the other element or intervening elements may also be present. Now, LCDs according to embodiments of the present invention will be specifically explained with reference to the accompanying drawings.

BRIEF DESCRIPTION OF THE DRAWINGS

The present invention will become more apparent by describing embodiments thereof in detail with reference to the accompanying drawings, in which:

FIGS. 1A, 1B, and 1C are block diagrams of an LCD having pixels structured according to a first embodiment of the present invention;

FIG. 2 is an equivalent circuit diagram of a pixel of an LCD according to the first embodiment of the present invention;

FIG. 3 is an equivalent circuit diagram of a sub-pixel of a pixel the LCD according to various embodiments of the present invention;

FIG. 4 is a plan view of a lower substrate (panel) for an LCD according to the first embodiment of the present invention;

FIG. 5 is a plan view of an upper substrate (panel) of an LCD according to the first embodiment of the present invention;

FIG. 6 is a plan view of a liquid crystal panel assembly with the lower substrate (panel) shown in FIG. 4 and the upper substrate (panel) shown in FIG. 5;

FIGS. 7 and 8 are cross-sectional views of the liquid crystal panel assembly of FIG. 6 taken along section line VII-VII and section line VIII-VIII-VIII";

FIG. 9 is a block diagram of an LCD comprising pixels structured according to a second embodiment of the present invention;

FIG. 10 is an equivalent circuit diagram of a pixel of an LCD according to the second embodiment of the present invention;

FIG. 11 is a plan view of a liquid crystal panel assembly according to the second embodiment of the present invention;

FIG. 12 is a cross-sectional view of the liquid crystal panel assembly of FIG. 11 taken along section line XII-XII line; and

FIG. 13 is an equivalent circuit diagram of a pixel of an LCD according to a third embodiment of the present invention.

DETAILED DESCRIPTION OF PREFERRED EMBODIMENTS

FIGS. 1A, 1B, and 1C each is a block diagram of an LCD according to one of three variations of a first embodiment of the present invention. FIG. 2 is an equivalent circuit diagram of a pixel of an LCD in any of the first embodiments of the present invention shown in FIGS. 1A, 1B, and 1C. FIG. 3 is an equivalent circuit diagram of one sub-pixel of a pixel in an LCD according to any of the first embodiments shown in FIGS. 1A, 1B, and 1C of the present invention.

As shown in FIGS. 1A, 1B, and 1C, an LCD according to the first embodiments of the present invention includes a liquid crystal panel assembly 300, a pair of gate drivers 400a and 400b (FIG. 1A) or a single gate driver 400 (FIG. 1B) connected to the liquid crystal panel assembly 300, a data

driver **500** connected to the liquid crystal panel assembly **300**, a gray voltage generator **800** connected to the data driver **500**, and a signal controller **600** for controlling them.

The liquid crystal panel assembly **300** includes a plurality of display signal lines (gate lines **G1a-Gnb**, and data lines **D1-Dm**), and a plurality (array) of pixels **PX** connected to those display signal lines (connected as shown in detail in FIG. 2) and arranged in the form of a matrix. Structurally, as shown in FIG. 3, the liquid crystal panel assembly **300** includes a first substrate (lower panel) **100** and a second substrate (an upper panel) **200** facing each other, and a liquid crystal layer **3** disposed between the two substrates (panels).

The display signal lines (gate lines **G1a-Gnb** and data lines **D1-Dm**) are provided on the first substrate (lower panel) **100**. The plurality of gate lines **G1a-Gnb** transmits gate signals (also called "scanning signals"), and the data lines **D1-Dm** transmits data signals. The gate lines **G1a-Gnb** extend in the (horizontal) direction of pixel rows (parallel to each other), and the data lines **D1-Dm** extend in the (vertical) direction of pixel columns (parallel to each other).

FIG. 2 illustrates an equivalent circuit of one pixel (**PX**) comprised of an "a" subpixel and a "b" subpixel each subpixel connected to corresponding display signal lines (gate lines **GLa** and **GLb** respectively, and data line **DL**). The display signal lines further include a storage electrode line **SL**. The storage electrode line **SL** extends (horizontally) parallel to the gate lines **GLa** and **GLb**.

Each of the pixels **PX** in the array of pixels includes a pair of sub-pixels **PXa** and **PXb**, and each of the sub-pixels **PXa** and **PXb** respectively includes a switching element **Qa** and **Qb**, a liquid crystal capacitor C_{LCa} and C_{LCb} connected to the switching element **Qa** and **Qb**, and a storage capacitor C_{STa} and C_{STb} , respectively. Each of the storage capacitors C_{STa} and C_{STb} is respectively connected to the corresponding switching element (**Qa** and **Qb**) and both are connected to the storage electrode line **SL**.

Referring to FIG. 3, the switching element **Q** (**Qa** or **Qb**) of each of the sub-pixels **PXa** and **PXb** is formed with a thin film transistor **TFT** formed on the first substrate (lower panel) **100**. The switching element **Q** (**Qa** or **Qb**) is a triode device with a control terminal (called a "Gate") connected to a gate line **GL**, an input terminal (called a "Source") connected to the data line **DL**, and an output terminal (called a "Drain"). The drain of the switching element **Q** (**Qa** or **Qb**) is connected to the liquid crystal capacitor C_{LC} and the storage capacitor C_{ST} .

As illustrated in FIG. 3, the liquid crystal capacitor C_{LC} has two terminals, comprised of the sub-pixel electrode **PE** of the first substrate (lower panel) **100** and the common electrode **CE** of the second substrate (upper panel) **200**, and a dielectric comprised of the liquid crystal layer **3** disposed between the two electrodes **PE** and **CE**. The sub-pixel electrode **PE** is connected to the switching element **Q**, and the common electrode **CE** may be formed over the entire surface of the second substrate (upper panel) **200** to receive a common voltage **Vcom**. Alternatively, in contrast with the structure shown in FIG. 3, the common electrode **CE** may be provided on the first substrate (lower panel) **100**, and in such case, either one or both of the two electrodes **PE** and **CE** may be formed in the shape of a line or a bar on the first substrate (lower panel) **100** adjacent to the other electrode.

The storage capacitor C_{ST} that is parallel to the liquid crystal capacitor C_{LC} is formed by overlapping the storage electrode line **SL** provided on the first substrate (lower panel) **100** with the pixel electrode **PE** while interposing an insulator, and a predetermined voltage such as a common voltage **Vcom** is applied to the storage electrode line **SL**. Alternatively, the storage capacitor C_{ST} may be formed by overlap-

ping the sub-pixel electrode **PE** with the gate line of a pixel of a different row while interposing an insulator.

Each of the respective pixels **PX** preferably expresses light of one of the primary colors (spatial division) or alternately expresses each of the primary colors in the temporal order (time division) such that the colors output by the pixel array can be perceived as the spatial or temporal sum of the primary colors. The primary colors include red, green, and blue colors.

FIG. 3 shows an example of the spatial division where each pixel has a color filter **CF** on the second substrate (upper panel) **200** that expresses one of the primary colors. Unlike the structure shown in FIG. 3, the color filter **CF** may alternatively be formed over or under the sub-pixel electrode **PE** on the second substrate (lower panel) **100**.

As shown in FIGS. 1A, 1B, and 1C, the gate driver(s) (**400a** and **400b**, or **400**) is connected to the plurality of gate lines **G1a-Gnb** to apply gate signals to the gate of the **TFT** in each subpixel (see FIG. 3). The gate signals are transmitted as binary signals at gate ON and gate OFF voltages (**Von** and **Voff**) received from the outside.

As shown in FIG. 1A, the pair of gate drivers **400a** and **400b** form a complete gate driver (like gate driver **400** as shown in FIGS. 1B and 1C) and are respectively located at the left and right sides of the liquid crystal panel assembly **300**, and are connected to the odd-numbered and the even-numbered gate lines **G1a-Gnb**, respectively. Alternatively, as shown in FIGS. 1B and 1C, one gate driver **400** is located at one side of the liquid crystal panel assembly **300**, and is connected to all the gate lines **G1a-Gnb**. As shown in FIG. 1C, two driving circuits **401** and **402** are built into the gate driver **400**, and are connected to the odd-numbered and the even-numbered gate lines **G1a-Gnb**, respectively.

The gray voltage generator **800** generates two sets of gray voltages (or reference gray voltage sets) related to the two light transmittances of each pixel (one light transmittance for each subpixel). The two different gray voltages are independently supplied to the two sub-pixels forming each one pixel. Each gray voltage set includes gray voltages having a positive value with respect to the common voltage **Vcom** and gray voltages having a negative value with respect to the common voltage **Vcom**. Alternatively, only a single (reference) gray voltage set may be generated instead of the two (reference) gray voltage sets.

The single data driver **500** is connected to all the data lines **D1-Dm** of the liquid crystal panel assembly **300** to select and output one of the selected one of the two gray voltage sets from the gray voltage generator **800**, and to apply one gray voltage of the selected gray voltage set to the sub-pixels as a data voltage. However, in the case that the gray voltage generator **800** does not supply all the gray voltages but only supplies the reference gray voltages, the data driver **500** divides the reference gray voltages and generates (outputs) all the gray voltages.

The gate driver **400** (or **400a** and **400b**) or the data driver **500** is directly mounted on the first substrate (lower panel) **100** in the form of one or more driving integrated circuit chips, or is mounted on a flexible printed circuit film (not shown) and attached to the liquid crystal panel assembly **300** in the form of a tape carrier package (TCP). By contrast, the gate driver **400** (or **400a** and **400b**) or the data driver **500** may be integrated on the first substrate (lower panel) **100**.

The signal controller **600** controls the operation of the gate driver **400** and the data driver **500**.

The structure of the liquid crystal panel assembly **300** will be now be specifically explained with reference to FIGS. 4 to 8.

FIG. 4 is a plan view of the first substrate (lower panel) 100 for an LCD according to the first embodiment of the present invention (FIGS. 1A, 1B, 1C), and FIG. 5 is a plan view of the second substrate (an upper panel) 200 for an LCD according to the first embodiment of the present invention. FIG. 6 is a combined plan view of a liquid crystal panel assembly with the first substrate (lower panel) shown in FIG. 4 and the second substrate (upper panel) shown in FIG. 5. FIGS. 7 and 8 are cross-sectional views of the liquid crystal panel assembly of FIG. 6 taken along section line VII-VII and section line VIII-VIII'-VIII'', respectively.

As shown in FIGS. 4 to 8, the LCD panel assembly according to the first embodiment includes a lower panel 100, an upper panel 200 facing the lower panel 100, and a liquid crystal layer 3 disposed between those panels.

The lower panel 100 will be specifically explained with reference to FIGS. 4, 6, 7 and 8.

Pairings of first and second gate lines 121a and 121b and a plurality of storage electrode lines 131 are formed on an insulating substrate 110 that may comprise transparent glass or plastic.

The first and second gate lines 121a and 121b extend (horizontally) parallel to each other, and are physically and electrically separated from each other, to transmit gate signals to the gates of TFTs in sub-pixels. The first and second gate lines 121a and 121b are arranged vertically. Each of the gate lines 121a has a plurality of first gate electrodes 124a and each of the gate lines 121b has a plurality of first gate electrodes 124b. The gate electrodes 124a and 124b protrude upward and downward. The first and second gate lines 121a and 121b also have left-side widened-area end portions (terminals) 129a and 129b to be connected to other layers or driving circuits. Alternatively, the end portions (terminals) 129a and 129b may be arranged at the right side of the first and second gate lines 121a and 121b, or at the left and right sides thereof respectively.

The storage electrode line 131 extends horizontally, and may be located closer to the first gate line 121a than to the second gate line 121b. The respective storage electrode lines 131 include a plurality of storage electrodes 133. The storage electrodes 133 are rectangular-shaped to be symmetrical with respect to the storage electrode lines 131. However, the shape and arrangement of the storage electrode lines 131 including the storage electrodes 133 may be altered in various manners. A predetermined voltage is applied to the storage electrode line 131, such as a common voltage applied to a common electrode 270 of the upper panel 200.

The gate lines 121a and 121b and the storage electrode line 131 are formed of an aluminum-based metallic material such as aluminum (Al) and an aluminum alloy, of a silver-based metallic material such as silver (Ag) and a silver alloy, of a copper-based metallic material such as copper (Cu) and a copper alloy, of a molybdenum-based metallic material such as molybdenum (Mo) and a molybdenum alloy, or of chromium (Cr), titanium (Ti), or tantalum (Ta). Alternatively, the gate lines 121a and 121b and the storage electrode line 131 may involve a multi-layered structure formed of two conductive layers (not shown) differentiated in physical properties thereof. One of the conductive layers is formed with a low resistivity metallic material such as an aluminum-based metallic material, a silver-based metallic material, and a copper-based metallic material such that it can reduce the signal delay or voltage drop of the gate lines 121a and 121b and the storage electrode line 131. By contrast, the other conductive layer is formed with a material having an excellent contact (adhesive) characteristic with respect to other materials like indium tin oxide ITO and indium zinc oxide IZO, such as a

molybdenum-based metallic material, chromium, titanium, and tantalum. Good examples of such a combination are a structure with a chromium-based under-layer and an aluminum- (alloy) based overlayer, and a structure with an aluminum- (alloy) based under-layer and a molybdenum- (alloy) based overlayer. In addition, the gate lines 121a and 121b and the storage electrode line 131 may be formed with various kinds of other metallic materials and conductors.

The lateral sides of the gate lines 121a and 121b and of the storage electrode line 131 are inclined with respect to the surface of the substrate 110, preferably at 30-80°.

A gate insulating layer 140 is formed of silicon nitride (SiNx) on the gate lines 121a and 121b and the storage electrode line 131.

A plurality of semiconductor islands 154a, 154b, 156a, and 157a are formed on the gate insulating layer 140 of hydrogenated amorphous silicon (abbreviated as a-Si) or of polysilicon. The semiconductor islands 154a and 154b are formed on the gate electrodes 124a and 124b, respectively.

A plurality of ohmic contacts 163a, 163b, 165a, 165b, and 166a are formed, on the semiconductor islands 154a, 154b, and 156a of silicide, or of n+ hydrogenated amorphous silicon wherein n-type impurities such as phosphorous are doped at a high concentration. A pair of the first ohmic contacts 163a and 163b and a pair of the second ohmic contact 165a and 165b are placed on the first and second semiconductor islands 154a and 154b, respectively. The third ohmic contact 166a is placed on the third semiconductor island 156a.

The lateral sides of the semiconductor islands 154a, 154b, 156a, and 157a and the ohmic contacts 163a, 163b, 165a, 165b, and 166a are inclined against the surface of the substrate 110 at 30-80°.

A plurality of data lines 171 and pairs of first and second drain electrodes 175a and 175b are formed on the ohmic contacts 163a, 163b, 165a, 165b, and 166a and the gate insulating layer 140.

The data lines 171 extend vertically such that they cross (over) the gate lines 121a and 121b and (over) the storage electrode line 131 to transmit data voltages to the pixels. The respective data lines 171 include a plurality of first and second source (TFT source) electrodes 173a and 173b extended toward the first and second gate electrodes 124a and 124b, respectively. The respective data lines 171 have end portions (terminals) 179 enlarged in width to facilitate making a connection with other layers or with external devices.

The first and second drain electrodes 175a and 175b are separated from the data lines 171, and face the source electrodes 173a and 173b around the gate electrodes 124a and 124b, respectively. The first and second drain electrodes 175a and 175b have bar-shaped end portions (terminals) placed on the semiconductor islands 154a and 154b, and have extensions 177a and 177b extended from the bar-shaped end portions and overlapped with the storage electrode 133 with a wide area. The bar-shaped end portions of the first and second drain electrodes 175a and 175b are partially surrounded by the U-shaped source electrodes 173a and 173b. The area of the extension 177b of the second drain electrode 175b is smaller than the area of the extension 177a of the first drain electrode 175a.

The first and second thin film transistors Qa and Qb are comprised of the semiconductor islands 154a and 154b together with the first and second gate electrodes 124a and 124b, the first and second source electrodes 173a and 173b, and the first and second drain electrodes 175a and 175b. The channels of the thin film transistors Qa and Qb are formed in the semiconductor islands 154a and 154b between the first

and second source electrodes **173a** and **173b** and the first and second drain electrodes **175a** and **175b**, respectively.

The data lines **171** and the drain electrodes **175a** and **175b** are preferably formed with a refractory metal such as molybdenum, chromium, tantalum, and titanium or an alloy thereof, or may comprise a multi-layered structure with a refractory metallic layer (not shown) and a low resistance conductive layer (not shown). Examples of the multi-layered structure are a double-layered structure with a chromium- or molybdenum- (alloy) based under-layer and an aluminum- (alloy) based overlayer, and a triple-layered structure with a molybdenum- (alloy) based underlayer, an aluminum- (alloy) based middle layer and a molybdenum- (alloy) based overlayer. In addition, the data lines **171** and the drain electrodes **175a** and **175b** may be formed of various other materials or conductors.

The drain electrodes **175a** and **175b** are inclined at 30-80° (like the gate lines **121a** and **121b** and the storage electrode lines **131**, the lateral sides of the data lines **171**).

The ohmic contacts **163a**, **163b**, **165a**, **165b**, and **166a** are located only between the underlying semiconductor islands **154a**, **154b**, **156a**, and **157a** and the overlying data line **171** and drain electrodes **175a** and **175b**, to lower the contact resistance. The semiconductor islands **154a** and **154b** have portions exposed through the source electrodes **173a** and **173b** and the drain electrodes **175a** and **175b**. The semiconductor islands **156a** and **157a** make the surface profile of the gate lines **121a** and **121b** and the storage electrode line **131** smooth, thereby preventing the data line **171** and the drain electrodes **175a** and **175b** from being cut.

A passivation layer **180** is formed on the data line **171**, the drain electrodes **175a** and **175b**, and the exposed portions of the semiconductor islands **154a** and **154b**. The passivation layer **180** is formed of an inorganic insulating material such as silicon nitride and silicon oxide, an organic insulating material, or a low dielectric insulating material. The organic insulating material and the low dielectric insulating material preferably have a dielectric constant of 4.0 or less, and examples of the low dielectric insulating material are a-Si:C:O and a-Si:O:F formed through plasma enhanced chemical vapor deposition (PECVD). The passivation layer **180** may be formed with an organic insulating material having photosensitivity, and the surface of the passivation layer **180** may be flattened. Alternatively, the passivation layer **180** may have a double-layered structure with an inorganic underlayer and an organic overlayer such that it bears the excellent insulating characteristic of the organic layer and does not harm the exposed portions of the semiconductor islands **154a** and **154b**.

A plurality of contact holes **182**, **185a**, and **185b** are formed through the passivation layer **180** so as to expose the end portions **179** of the data line **171** and the extensions **177a** and **177b** of the drain electrodes **175a** and **175b**, respectively. A plurality of contact holes **181a** and **181b** are formed through the passivation layer **180** and the gate insulating layer **140** so as to expose the end portions **129a** and **129b** of the gate lines **121a** and **121b**.

A plurality of pixel electrodes **190** (comprised of first and second sub-pixel electrodes **190a** and **190b**), shielding electrodes **88**, and a plurality of contact assistants **81a**, **81b**, and **82** are formed on the passivation layer **180** with a transparent conductive material such as ITO and IZO, or a reflective metallic material such as aluminum, silver, and alloys thereof.

The first and second sub-pixel electrodes **190a** and **190b** are physically and electrically connected to the first and second drain electrodes **175a** and **175b** through the contact holes **185a** and **185b** to receive data voltages from the first and second drain electrodes **175a** and **175b**. Different predeter-

mined voltages are applied to the sub-pixel electrode pairs **190a** and **190b** with respect to one input image signal (one image data corresponding to the luminance of one color), and the magnitudes thereof are determined depending upon the sizes and shape of the sub-pixel electrodes **190a** and **190b**. Furthermore, the areas of the sub-pixel electrodes **190a** and **190b** may differ from each other. For instance, the second sub-pixel electrode **190b** may receive a voltage higher than that of the first sub-pixel electrode **190a**, while it is smaller in area than the first sub-pixel electrode **190a**.

Upon receipt of the data voltages, the sub-pixel electrodes **190a** and **190b** together with the common electrode **270** generate electric fields, and the electric fields align the liquid crystal molecules of the liquid crystal layer **3** between the two electrodes **190** (**190a** and **190b**) and **270**.

As explained earlier, the sub-pixel electrodes **190a** and **190b** and the common electrode **270** (the liquid crystal molecules of the dielectric liquid crystal layer **3**) form liquid crystal capacitors C_{LCa} and C_{LCb} to sustain the voltages applied thereto even after the thin film transistors **Qa** and **Qb** are turned OFF. Storage capacitors C_{STa} and C_{STb} are arranged parallel to the liquid crystal capacitors C_{LCa} and C_{LCb} to reinforce the voltage storage capacity (to maintain the electric field even after the thin film transistors **Qa** and **Qb** are turned OFF). The storage capacitors C_{STa} and C_{STb} are formed by overlapping the first and second sub-pixel electrodes **190a** and **190b** over the extensions **177a** and **177b** of the drain electrodes **175a** and **175b** connected thereto with the storage electrodes **133**.

As the first sub-pixel electrode **190a** is larger in area than the second sub-pixel electrode **190b**, the capacitance of the first liquid crystal capacitor C_{LCa} is greater than that of the second liquid crystal capacitor C_{LCb} . As the extension **177a** of the first drain electrode **175a** overlapping the storage electrode **133** is larger in area than the extension **177b** of the second drain electrode **175b**, the capacitance of the first storage capacitor C_{STa} is greater than the capacitance of the second storage capacitor C_{STb} . Accordingly, the current driving ability of the first thin film transistor **Qa** should be greater than that of the second thin film transistor **Qb**, and the W/L value of the first thin film transistor **Qa** where W is the channel width and L is the channel length is correspondingly higher than the W/L value of the second thin film transistor **Qb**.

The four corners of the respective pixel electrodes **190** are edge-cut at, and the cut leg is angled against the gate lines **121a** and **121b** at 45°.

A pair of the first and second sub-pixel electrodes **190a** and **190b** (forming one pixel electrode **190**) are intermixed with each other while separated by a gap **94**, and the whole pixel electrode **190** is outlined roughly having a rectangular shape. The second sub-pixel electrode **190b** is shaped as an equilateral trapezoid having a trapezoid-hollowed base. The second sub-pixel electrode **190b** is mostly surrounded by the first sub-pixel electrode **190a**. The first sub-pixel electrode **190a** is formed with an upper trapezoid, a lower trapezoid, and a middle trapezoid connected to each other at the left side thereof. The first sub-pixel electrode **190a** has cutouts **95a**, **95b**, and **95c** extended from the top side of the upper trapezoid and the bottom side of the lower trapezoid to the right side thereof. The gate line **121a** proceeds between the cutouts **95a** and **95b**. The middle trapezoid of the first sub-pixel electrode **190a** is fitted into the hollowed base of the second sub-pixel electrode **190b**. The first sub-pixel electrode **190a** has a cutout **92** extended along the storage electrode line **131**, and the cutout **92** has an entrance at the left side of the first sub-pixel electrode **190a** and a horizontal portion horizontally extended from the entrance. The entrance of the cutout **92** has a pair of

legs angled against the storage electrode line **131** at 45° . The gap **94** between the first and second sub-pixel electrodes **190a** and **190b** has two pairs of upper and lower inclined portions angled against the gate lines **121a** and **121b** at 45° with a substantially even width, and three vertical portions with a substantially even width. For explanatory convenience, the gap **94** will be also referred to as a cutout. The cutouts **92**, **94**, **95a**, **95b**, and **95c** are inversion-symmetrical to the storage electrode line **131**, and are angled against the gate lines **121a** and **121b** at 45° while extending vertical to each other. The pixel electrode **190** is partitioned into a plurality of domains due to the cutouts **92**, **94**, **95a**, **95b**, and **95c**.

Accordingly, the pixel electrode **190** is horizontally bisected around the storage electrode line **131**, and the upper half and the lower half of the pixel electrode **190** are divided into four domains by way of the cutouts **92**, **94** and **95a-95c**, respectively. The number of divided domains or cutouts varies depending upon the design factors such as a pixel size, the length ratio of the horizontal to the vertical sides of the pixel electrode **190**, and the kind or characteristics of the liquid crystal layer **3**.

The first sub-pixel electrode **190a** is overlapped by the first and second gate lines **121a** and **121b**, and the second sub-pixel electrode **190b** is overlapped by the first gate line **121a**. The first gate line **121a** proceeds at the center of the upper half of the pixel electrode **190**.

The shielding electrode **88** (**88a**) has a vertical portion proceeding along the data line **171**, and a horizontal portion proceeding along the second gate line **121b**. The vertical portion of the shielding electrode **88** completely covers the data line **171**, and the horizontal portion thereof is placed internal to the boundary of the gate line **121b**. The shielding electrode **88** is connected to the storage electrode line **131** through contact holes (not shown) through the passivation layer **180** and the gate insulating layer **140**, or to a short point (not shown) for relaying the common voltage V_{com} from the lower panel **100** to the upper panel **200**.

The shielding electrode **88** receives the common voltage V_{com} , and shields the electric fields formed between, the data line **171** and the pixel electrode **190** as well as between the data line **171** and the common electrode **270**, thereby preventing voltage distortion of the pixel electrode **190** and signal delay of the data voltage transmitted by the data line **171**.

Furthermore, the pixel electrode **190** and the shielding electrode **88** should be spaced apart from each other to prevent them from short-circuiting each other. Therefore, the pixel electrode **190** is far enough apart from the data line **171** so that the parasitic capacitance therebetween is reduced. Moreover, as the permittivity of the liquid crystal layer **3** is higher than that of the passivation layer **180**, in the absence of the shielding electrode **88**, the parasitic capacitance between the data line **171** and the shielding electrode **88** is smaller than that between the data line **171** and the common electrode **270**.

Moreover, as the pixel electrode **190** and the shielding electrode **88** are formed on the same layer, the distance therebetween is even, and accordingly the parasitic capacitance therebetween is approximately constant. In order to minimize the reduction in aperture ratio, the distance between the shielding electrode **88** and the pixel electrode **190** is preferably minimized.

However, when necessary, such a shielding electrode **88** may be omitted.

The contact assistants **81a**, **81b**, and **82** are connected to the end portions (terminals) **129a** and **129b** of the gate lines **121a** and **121b** and the end portion (terminal) **179** of the data line **171** through the contact holes **181a**, **181b**, and **182**, respectively. The contact assistants **81a**, **81b**, and **82** serve to

increase the adhesion between the exposed end portions (terminals) **129a** and **129b** of the gate lines **121a** and **121b** and the exposed end portion (terminal) **179** of the data line **171** and external devices, and to protect them.

An alignment layer **11** is formed on the pixel electrode **190**, the shielding electrode **88**, the contact assistants **81a**, **81b**, and **82**, and the passivation layer **180** to align the liquid crystal layer **3**. The alignment layer **11** may be a horizontal alignment layer.

The second substrate (upper panel) **200** will now be specifically explained with reference to FIGS. **5** to **8**.

A light blocking member **220** provided to prevent leakage of light, called the black matrix, is formed on an insulating substrate **210** made of transparent glass. The light blocking member **220** has a plurality of opening portions with the same shape and location as the pixel electrodes **190**. Alternatively, the light blocking member **220** may be formed over a portion corresponding to the data line **171**, and over portions corresponding to the thin film transistors **Qa** and **Qb**. However, the light blocking member **220** may be formed with various shapes to prevent the leakage of light around the pixel electrode **190** and the thin film transistors **Qa** and **Qb**.

A plurality of color filters **230** are formed on the insulating substrate **210**. The color filters **230** are mostly placed within the opening portions of (region surrounded by) the light blocking member **220**, and they extend vertically and longitudinally along the pixel electrode **190**. The color filters **230** may express one of the three primary colors of red, green, and blue.

A transparent overcoat layer **250** is formed over the color filters **230** and over the light blocking member **220** to prevent the color filters **230** from being exposed, and to provide a flat surface.

A common electrode **270** is formed on the overcoat layer **250** with a transparent conductive material such as ITO and IZO.

As shown in FIG. **5**, the common electrode **270** has a plurality of sets of cutouts **73**, **74**, **75a**, **75b**, **76a**, and **76b**.

The set of the cutouts **73-76b** face one pixel electrode **190**, and they include middle cutouts **73** and **74**, upper cutouts **75a** and **76a**, and lower cutouts **75b** and **76b**. As shown in FIG. **6**, the cutouts **73-76b** are positioned between the neighboring cutouts **92-95c** of the pixel electrode **190** as well as between the peripheral cutouts **95a-95c** and the corners of the pixel electrode **190**. Furthermore, the respective cutouts **73-76b** include at least one inclined portion extended parallel to the cutouts **92-95c** of the pixel electrode **190**.

The upper and lower cutouts **75a-76b** include an inclined portion extended from the right side of the pixel electrode **190** toward the bottom or the top side thereof, and horizontal and vertical portions extended from the respective ends of the inclined portion along the sides of the pixel electrode **190** while being overlapped with those sides and obtuse-angled against the inclined portion.

The first middle cutout **73** has a pair of inclined portions obliquely extended from the storage electrode **133** to the left side of the pixel electrode **190**, and vertical end portions extended from the ends of the inclined portions along the left side of the pixel electrode **190** while being overlapped with the left side of the pixel electrode **190** and obtuse-angled against the inclined portions. The second middle cutout **74** includes a vertical portion extended along the right side of the pixel electrode **190** while being overlapped therewith, a pair of inclined portions extended from the respective ends of the vertical portion toward the left side of the pixel electrode **190**, and vertical end portions extended from the ends of the inclined portions along the left side of the sub-pixel electrode

190b while being overlapped with the left side and obtuse-angled against the inclined portions.

Triangle-shaped notches are formed at the inclined portions of the cutouts 73-76b. The notches may be formed in the shape of a rectangle, a trapezoid, or a semi-circle, or they may be concave or convex. The notches determine the arrangement of the liquid crystal molecules 3 located at the regional boundary corresponding to the cutouts 73-76b.

The number of the cutouts 73-76b may be varied depending upon the design factors, and the light blocking member 220 may be overlapped with the cutouts 73-76b to prevent the leakage of light around the cutouts 73-76b.

As the same common voltage is applied to the common electrode 270 and the shielding electrode 88, an electric field does not exist between those electrodes. Accordingly, the liquid crystal molecules disposed between the common electrode 270 and the shielding electrode 88 continuously hold the initial vertical alignment state thereof, and the light incident thereto is intercepted.

An alignment layer 21 is formed on the common electrode 270 and the overcoat 250 to align the liquid crystal layer 3. The alignment layer 21 may be a horizontal alignment layer.

Polarizers 12 and 22 are provided on the outer surfaces of the panels 100 and 200, and the light transmission axes of the two polarizer plates 12 and 22 are typically perpendicular to each other. One of the light transmission axes of the two polarizers 12 and 22 (or the light absorption axis thereof) proceeds in the horizontal direction. In the case of a reflection type of LCD, one of the two polarizers 12 and 22 may be omitted.

The liquid crystal layer 3 may have a negative dielectric anisotropy, and the liquid crystal molecules of the liquid crystal layer 3 may be vertically aligned with respect to the surfaces of the two panels with no application of a voltage (absent an electric field).

When a common voltage is applied to the common electrode 270 and a data voltage is applied to the pixel electrode 190, an electric field is generated across the liquid crystal layer 3 between the surfaces of the panels 100 and 200. The cutouts 92-95c and 73-76b of the electrodes 190 and 270 deform the electric field, and create electric field components between the sides (edges) of the cutouts 92-95c and 73-76b.

Accordingly, the electric field is locally inclined with respect to the direction across and between the surfaces of the panels 100 and 200. Thus the liquid crystal molecules are aligned in response to the deformed electric field(s) such that the directors thereof are along to the deformed electric field. At this time, the electric fields formed around the cutouts 92-95c and 73-76b and the sides of the pixel electrode 190 do not proceed parallel to the directors of the liquid crystal molecules, but are angled against the latter at a predetermined angle. Therefore, the liquid crystal molecules are rotated on the plane between the directors of the liquid crystal molecules and the electric fields in the direction with a short movement distance. Consequently, a set of the cutouts 92-95c and 73-76b and the sides of the pixel electrode 190 partition the portion of the liquid crystal layer 3 placed on the pixel electrode 190 into a plurality of domains where the inclination directions of the liquid crystal molecules differ from each other, and hence the reference viewing angle is enlarged.

At least one of the cutouts 92-95c and 73-76b may be replaced by a protrusion or a hollowed portion, and the shape and arrangement of the cutouts 92-95c and 73-76b may be varied.

The display operation of the LCD according to the first embodiment will now be further explained in detail.

The signal controller 600 receives (from an external graphics controller, not shown) input image (color image data) signals R, G, and B and input control signals for controlling the displaying thereof such as vertical synchronization signals Vsync, horizontal synchronization signals Hsync, main clock signals MCLK, and data enable signals DE. The signal controller 600 suitably processes the image (color image data) signals R, G, and B pursuant to the operation conditions of the liquid crystal panel assembly 300. Based on the input (color image data) image signals R, G, and B and the input control signals, the signal controller 600 generates gate control signals CONT1 and data control signals CONT2. The signal controller 600 transmits the gate control signals CONT1 to the gate driver 400, and the data control signals CONT2 and the processed image signals DAT to the data driver 500.

The gate control signals CONT1 include scanning start signals STV for instructing to start the scanning of the "gate ON" voltage Von, and at least one clock signal for controlling the output of the "gate ON" voltage Von.

The data control signals CONT2 include horizontal synchronization start signals STH for informing of the data transmission to one pixel row, load signals LOAD for applying the relevant data voltages to the data lines D1-Dm, and data clock signals HCLK. The data control signals CONT2 may include reverse signals RVS for inverting the polarity of the data voltage with respect to the common voltage Vcom (referred to hereinafter as reversing "the polarity of the data voltage").

The data driver 500 receives image data DAT for a pair of sub-pixels PXa and Pxb in accordance with the data control signals CONT2 from the signal controller 600, and selects one set of gray voltages from among the two sets of gray voltages from the gray voltage generator 800. The data driver 500 further selects the gray voltages corresponding to the respective image data DAT from the selected set of gray voltages, and suitably converts the image data DAT into data voltages to transmit them to the relevant data lines D1-Dm.

Alternatively, a separate external selecting circuit (not shown) may select one set of gray voltages from the two sets of gray voltages, and transmit them to the data driver 500. Furthermore, the gray voltage generator 800 may provide a reference voltage that varies in value, and the data driver 500 may divide the reference voltage to make gray voltages.

The gate driver 400 applies the "gate ON" voltages Von to the gate lines G1a-Gnb in accordance with the gate control signals CONT1 from the signal controller 600 to turn ON the switching elements Qa and Qb connected to the gate lines G1a-Gnb, and accordingly, the data voltages applied to the data lines D1-Dm are applied to the relevant sub-pixels PXa and Pxb via the turned-ON switching elements Qa and Qb.

The difference between the data voltage applied to the sub-pixels PXa and Pxb and the common voltage Vcom is represented by the charge voltage of the liquid crystal capacitor C_{LC} , that is, by the pixel voltage. The liquid crystal molecules are reoriented depending upon the magnitudes of the pixel voltages, and accordingly the polarization of the light passing through the liquid crystal layer 3 is varied. The polarization variation is represented by the variation in light transmittance by way of the polarizers (not shown) attached to the substrates (panels) 100 and 200.

The two sets of gray voltages explained earlier indicate different gamma curves, and as they are applied to the two sub-pixels PXa and Pxb of one pixel PX, the gamma curve of one pixel PX becomes a mixture curve thereof. When the two sets of gray voltages are determined, the mixture gamma curve is established to be closer to the front side reference gamma curve. For instance, the front side mixture gamma

curve corresponds to an optimally-determined front side reference gamma curve, and the lateral side mixture gamma curve is established to be closest to the front side reference gamma curve. In this way, the lateral side visibility can be enhanced.

As explained previously, the area of the second sub-pixel electrode **190b** receiving a relatively higher voltage may be established to be smaller than that of the first sub-pixel electrode **190a** so as to reduce the deformation in the lateral side gamma curve. For example, in the case that the area ratio of the first sub-pixel electrode **190a** to the second sub-pixel electrode **190b** is about 2:1, the lateral side gamma curve becomes closer to the front side gamma curve so that the lateral side visibility can be enhanced.

With a $\frac{1}{2}$ horizontal period (or $\frac{1}{2}H$, a half period of horizontal synchronization signals Hsync), the data driver **500** and the gate driver **400** repeat the same operation. In this way, the “gate ON” voltages V_{on} are sequentially applied to all the gate lines $G1a-Gnb$ for one frame, row by row, thereby applying the data voltages to all the pixels PX. When one frame is terminated, the next frame starts, and the reverse signals applied to the data driver **500** are controlled such that the polarity of the data voltage applied to the respective pixels PX is opposite to that in the previous frame (“frame inversion”). At this time, the polarities of the data voltages flowing through one data line may be inverted depending upon the characteristic of the reverse signals RVS even within one frame (for instance, a row inversion or a dot inversion), or the polarities of the data voltages simultaneously flowing through neighboring data lines may differ from each other (for instance, a column inversion or a dot inversion).

Meanwhile, as shown in FIG. 3, the kickback voltage V_k as defined in the following Equation 1 is generated by the coupling due to the parasitic capacitance C_{gd} between the control and the output terminals of the switching element Q when the “gate ON” voltage V_{on} is converted into the “gate OFF” voltage V_{off} , and lowers the voltage applied to the pixel electrode PE.

$$V_k = \frac{C_{gd}}{C_{LC} + C_{ST} + C_{gd}} \Delta V_g \quad \text{Equation 1}$$

where ΔV_g is the difference voltage between the “gate ON” voltage V_{on} and the “gate OFF” voltage V_{off} .

With the LCD according to the first embodiment of the present invention, the magnitudes of the kickback voltages V_{ka} and V_{kb} of the first and second sub-pixels PXa and PXb are substantially the same. The capacitance values of the liquid crystal capacitors C_{LCa} and C_{LCb} of the first and second sub-pixels PXa and PXb are determined depending upon the area ratio of the first sub-pixel electrode **190a** to the second sub-pixel electrode **190b**, and the parasitic capacitances C_{gda} and C_{gdb} are also determined depending upon the design factors. Accordingly, the areas of the first and second drain electrodes **175a** and **175b** that are overlapped with the storage electrode **133** are suitably controlled to produce the capacitance values of the first and second storage capacitors C_{STa} and C_{STb} that are capable of making the magnitudes of the kickback voltages V_{ka} and V_{kb} the same. In addition, the gate signals applied to the first and second sub-pixels PXa and PXb may be differentiated from each other. For instance, the magnitudes of the “gate ON” voltages V_{on} are differentiated to control the value of ΔV_g , thereby making the magnitudes of the kickback voltages V_{ka} and V_{kb} the same. In this way, the magnitudes of the kickback voltages V_{ka} and V_{kb} of the

first and second sub-pixels PXa and PXb are controlled to be the same, thereby preventing the display screen from flickering.

An LCD according to a second embodiment of the present invention will now be specifically explained with reference to FIGS. 9 and 10.

FIG. 9 is a block diagram of an LCD according to the second embodiment of the present invention, and FIG. 10 is an equivalent circuit diagram of a pixel (PX) of the LCD of FIG. 9 according to the second embodiment of the present invention.

An LCD according to the second embodiment of the present invention includes a liquid crystal panel assembly **301**, a gate driver **403** and a data driver **501** connected to the liquid crystal panel assembly **301**, a gray voltage generator **801** connected to the data driver **501**, and a signal controller **601** for controlling them.

The liquid crystal panel assembly **301** includes a plurality of display signal lines $G1-Gn$ and $D1-D2m$, and a plurality (array) of pixels PX connected to those signal lines and arranged in the form of a matrix.

The display signal lines ($G1-Gn$ and $D1-D2m$) include a plurality of gate lines $G1-Gn$ for transmitting gate signals to the pixels PX, and a plurality of data lines $D1-D2m$ for transmitting data signals to the pixels PX. The gate lines $G1-Gn$ extend (horizontally) in the pixel row direction substantially parallel to each other, and the data lines $D1-D2m$ extend (vertically) in the pixel column direction substantially parallel to each other. The data lines $D1-D2m$ are provided at both sides of each pixel PX in each column. The display signal lines may include storage electrode lines proceeding parallel to the gate lines $G1-Gn$ in addition to the gate lines $G1-Gn$ and the data lines $D1-D2m$.

FIG. 10 illustrates an equivalent circuit of one pixel PX and the display signal lines connected thereto. The display signal lines connected to each pixel PX include a gate line indicated by GL, data lines indicated by DL_a and DL_b, and a storage electrode line SL proceeding parallel to the gate line GL.

Each of the respective pixels PX includes a pair of sub-pixels PXc and PXd. The respective sub-pixels PXc and PXd include switching elements Qc and Qd connected to the shared gate line GL and to data lines DL_a and DL_b, and to liquid crystal capacitors C_{LCc} and C_{LCd} and storage capacitors C_{STc} and C_{STd} connected thereto.

The respective sub-pixels PXc and PXd are substantially the same as those shown in FIG. 3, and hence further explanation thereof would be redundant and is omitted.

The gray voltage generator **801** generates two sets of gray voltages related to the light transmittance of the sub-pixels PXc and PXd. One set of the two sets of gray voltages has a positive value with respect to the common voltage V_{com} , and the other set has a negative value.

The gate driver **403** is connected to the gate lines $G1-Gn$ of the liquid crystal panel assembly **301** to apply gate signals with combinations of the “gate ON” and “gate OFF” voltages V_{on} and V_{off} from the outside to the gate lines $G1-Gn$.

The data driver **501** is connected to the data lines $D1-D2m$ of the liquid crystal panel assembly **301** to select the gray voltages from the gray voltage generator **801** and apply them to the sub-pixels PXc and PXd of each pixel PX as data signals.

The signal controller **601** controls the operation of the gate driver **403** and of the data driver **501**.

The structure of the liquid crystal panel assembly **301** will now be specifically explained with reference to FIGS. 11 and 12.

FIG. 11 is a plan view of a representative Pixel PX in the liquid crystal panel assembly 301 according to the second embodiment of the present invention (FIG. 9), and FIG. 12 is a cross-sectional view of the pixel PX in the liquid crystal panel assembly 301 of FIG. 11 taken along section line XII-XII.

As shown in FIGS. 11 and 12, the liquid crystal panel assembly 301 includes a first substrate (lower panel 101, a second substrate (upper panel) 201 facing the first substrate (lower panel 101, and a liquid crystal layer 3 disposed between those substrates (panels 101 and 201).

The first substrate (lower panel) 101 will be explained in detail first.

A plurality of gate lines 121 and a plurality of storage electrode lines 131a are formed on an insulating substrate 110 (e.g., made of transparent glass).

The gate lines 121 extend horizontally and are separated from each other, and they transmit gate signals. Each of the gate lines 121 include a plurality of protrusions forming a plurality of gate electrodes 124c and 124d, and a wide end portion 129 for making a connection with other layers or external devices.

Each of the storage electrode lines 131a extends horizontally, and includes a plurality of protrusions forming storage electrodes 133a and 133b. The storage electrodes 133a and 133b are rectangular-shaped symmetrical to the storage electrode line 131a. The area of the first storage electrode 133a is larger than the area of the second storage electrode 133b.

A gate insulating layer 140 is formed of silicon nitride (SiN_x) upon the gate line 121 and upon the storage electrode line 131a.

A plurality of semiconductor islands 154c, 154d, 156b, and 157b are formed on the gate insulating layer 140 with hydrogenated amorphous silicon or polycrystalline silicon. The semiconductor islands 154c and 154d are placed over the gate electrodes 124c and 124d, respectively.

A plurality of ohmic contacts 163c, 163d, 165c, 165d, 166b, and 167 are formed on the semiconductor islands 154c, 154d, 156b, and 157b with silicide or n+hydrogenated amorphous silicon doped with n type impurities such as phosphorous at a high concentration. A pair of the first and third ohmic contacts 163c and 165c and a pair of the second and fourth ohmic contacts 163d and 165d are placed on the first and second semiconductor islands 154c and 154d, and the fifth and sixth ohmic contacts 166b and 167 are placed on the third and fourth semiconductor islands 156b and 157b.

A plurality of data lines 171a and 171b and a plurality of drain electrodes 175c and 175d separated from those data lines are formed on the gate insulating layer 140 and the ohmic contacts 163c, 163d, 165c, 165d, 166b, and 167.

The data lines 171a and 171b extend vertically, and cross the gate line 121 and the storage electrode line 131a to transmit data voltages. The data lines 171a and 171b include a plurality of source electrodes 173c and 173d extended toward the gate electrodes 124c and 124d, and end portions 179a and 179b enlarged in width to make a connection with other layers or external devices.

The first and second drain electrodes 175c and 175d are separated from the data lines 171a and 171b, and face the source electrodes 173c and 173d around the gate electrodes 124c and 124d, respectively. The first and second drain electrodes 175c and 175d have bar-shaped end portions placed on the semiconductor islands 154c and 154d, and wide area extensions 177c and 177d extended from the bar-shaped end portions and overlapped with the storage electrodes 133a and 133b, respectively. The bar-shaped end portions are partially surrounded by the U-shaped source electrodes 173c and

173d. The area of the extension 177d of the second drain electrode 175d is smaller than the area of the extension 177c of the first drain electrode 175c.

The first and second thin film transistors Qc and Qd are formed of the first and second gate electrodes 124c and 124d, the first and second source electrodes 173c and 173d, and the first and second drain electrodes 175c and 175d together with the semiconductor islands 154c and 154d. The channels of the thin film transistors Qc and Qd are formed at the semiconductor islands 154c and 154d between the first and second source electrodes 173c and 173d and the first and second drain electrodes 175c and 175d.

The ohmic contacts 163c, 163d, 165c, 165d, 166b, and 167 only exist between the underlying semiconductor islands 154c, 154d, 156b, and 157b and the overlying data lines 171a and 171b and drain electrodes 175c and 175d to lower the contact resistance. The island-shaped semiconductor islands 154c and 154d have portions exposed through the source electrodes 173c and 173d and the drain electrodes 175c and 175d. The semiconductor islands 156b and 157b makes the surface profile of the gate line 121 and the storage electrode line 131a smooth, thereby preventing the data lines 171a and 171b and the drain electrodes 175c and 175d from being cut.

A passivation layer 180 is formed on the data lines 171a and 171b, the drain electrodes 175c and 175d and the exposed portions of the semiconductor islands 154c and 154d.

A plurality of contact holes 185c, 185d, 182a, and 182b are formed at the passivation layer 180 such they expose the extensions 177c and 177d of the drain electrodes 175c and 175d, and the end portions (terminals) 179a and 179b of the data lines 171a and 171b, respectively. A plurality of contact holes 181 are formed at the passivation layer 180 and the gate insulating layer 140 such that they expose the end portions (terminals) 129 of the gate lines 121.

A plurality of pixel electrodes 191 with first and second sub-pixel electrodes 191a and 191b, a plurality of shielding electrodes 88b, and a plurality of contact assistants 81, 82a, and 82b are formed on the passivation layer 180.

The first and second sub-pixel electrodes 191a and 191b are physically and electrically connected to the first and second drain electrodes 175c and 175d through the contact holes 185c and 185d to receive data voltages from the first and second drain electrodes 175c and 175d. Different predetermined data voltages with respect to one input image (data) signal are applied to each pair of the sub-pixel electrodes 191a and 191b, and the magnitudes thereof depend upon the size and shape of the sub-pixel electrodes 191a and 191b. Furthermore, the areas of the sub-pixel electrodes 191a and 191b may differ from each other. For example, the second sub-pixel electrode 191b may receive a voltage higher than that applied to the first sub-pixel electrode 191a, and may be smaller in area than the first sub-pixel electrode 191a.

The sub-pixel electrodes 191a and 191b receiving the data voltages together with the common electrode 270 generate electric fields that determine the arrangement of the liquid crystal molecules of the liquid crystal layer between the two electrodes 191 and 270.

As explained earlier, the respective sub-pixel electrodes 191a and 191b and the common electrode 270 form liquid crystal capacitors C_{LCc} and C_{LCd} to sustain the applied voltage even after the thin film transistors Qc and Qd turn OFF. In order to increase the voltage storage capacity, storage capacitors C_{STc} and C_{STd} are connected in parallel to the liquid crystal capacitors C_{LCc} and C_{LCd} by overlapping the first and second sub-pixel electrodes 191a and 191b and the extensions 177c and 177d of the drain electrodes 175c and 175d connected thereto with the storage electrodes 133a and 133b.

Since the first sub-pixel electrode **191a** is larger in area than the second sub-pixel electrode **191b**, the first liquid crystal capacitor C_{LCc} has a capacitance greater than the second liquid crystal capacitor C_{LCd} . Since the storage electrode **133a** and the extension **177c** of the first drain electrode **175c** overlapped therewith are larger in area than the storage electrode **133b** and the extension **177d** of the second drain electrode **175d** overlapped therewith, the first storage capacitor C_{STc} has a capacitance greater than the second storage capacitor C_{STd} . Accordingly, the first thin film transistor Qc may have a current driving capacity greater than that of the second thin film transistor Qd, and hence the value of W/L of the first thin film transistor Qc may be higher than the value of W/L of the second thin film transistor Qd.

A pair of first and second sub-pixel electrodes **191a** and **191b** forming one pixel electrode **191** engage with each with a gap **93** interposed therebetween, and the outline of the pixel electrode **191** has roughly a rectangular shape. The second sub-pixel electrode **191b** is shaped as a rotated equilateral trapezoid having a trapezoid-hollowed base. The second sub-pixel electrode **191b** is mostly surrounded by the first sub-pixel electrode **191a**. The first sub-pixel electrode **191a** is formed with an upper trapezoid, a lower trapezoid, and a middle trapezoid connected to each other at the left side thereof. The middle trapezoid of the first sub-pixel electrode **191a** is fitted into the hollowed base of the second sub-pixel electrode **191b**. The gap **93** between the first and second sub-pixel electrodes **191a** and **191b** has two pairs of upper and lower inclined portions angled against the gate line **121** at 45° with a substantially even width, and three vertical portions with a substantially even width. For explanatory convenience, the gap **93** will also be referred to as a cutout.

The first sub-pixel electrode **191a** has cutouts **96a**, **96b**, **97a**, and **97b** extended from the top side of the upper trapezoid and the bottom side of the lower trapezoid to the right side thereof. The first sub-pixel electrode **191a** has cutouts **91** and **92a** extended along the storage electrode line **131a**, and the cutouts **91** and **92a** have a horizontal portion extended from the center in the horizontal direction, and a pair of legs angled against the storage electrode line **131a** at 45° . The second sub-pixel electrode **191b** has cutouts **94a** and **94b** extended from the left side thereof toward the right side. The cutouts **91**, **92a**, **94a**, **96a**, **96b**, **97a**, and **97b** are nearly inversion-symmetrical to the storage electrode line **131a**, and they proceed vertical to each other while being angled against the gate line **121** at 45° . The upper half and the lower half of the pixel electrode **191** are partitioned into eight domains by way of the cutouts **91-97b**, respectively.

The shielding electrode **88b** has vertical portions extended along the data lines **171a** and **171b**, and a horizontal portion extended along the gate line **121**. The vertical portions of the shielding electrode **88b** completely cover the data lines **171a** and **171b**, and the horizontal portion thereof also completely covers the gate line **121**.

The shielding electrode **88b** shields the electric fields formed between the data lines **171a** and **171b** and the pixel electrode **191** as well as between the data lines **171a** and **171b** and the common electrode **270**, thereby reducing the voltage distortion of the pixel electrode **191** and the signal delay of the data voltage transmitted by the data lines **171a** and **171b**. In order to prevent the short-circuiting between the pixel electrode **191** and the shielding electrode **88b**, they are spaced apart from each other, and hence the pixel electrode **191** is far apart from the data lines **171a** and **171b** and the gate line **121**, thereby reducing the parasitic capacitance therebetween.

The contact assistants **81**, **82a**, and **82b** are connected to the end portion (terminal) **129** of the gate line **121** and the end

portions (terminals) **179a** and **179b** of the data lines **171a** and **171b** through the contact holes **181**, **182a**, and **182b**, respectively.

An alignment layer **11** is formed on the pixel electrode **191**, the contact assistants **81**, **82a**, and **82b** and the passivation layer **180** to align the liquid crystal layer **3**.

The second substrate (upper panel) **201** will be now explained in detail with reference to FIGS. **11** and **12**.

A light blocking member **220**, a plurality of color filters **230**, an overcoat layer **250**, and a common electrode **270** are sequentially formed on an insulating substrate **210** (e.g., made of transparent glass).

The portion of the common electrode **270** corresponding to (overlapping) one pixel has a set of cutouts **71**, **72**, **73a**, **74a**, **75c**, **75d**, **76c**, **76d**, **77a**, **77b**, **78a**, and **78b**. Thus, the common electrode **270** has a plurality of sets of cutouts **71-78b**.

A set of the cutouts **71-78b** face one pixel electrode **191**, and include middle cutouts **71**, **72**, **73a**, and **74a**, upper cutouts **75c**, **76c**, **77a**, and **78a** and lower cutouts **75d**, **76d**, **77b**, and **78b**. The cutouts **71-78b** are arranged at the center of the left side of the pixel electrode **191**, between the neighboring cutouts **91-97b** of the pixel electrode **191**, and between the peripheral cutouts **97a** and **97b** and the corners of the pixel electrode **191**. Furthermore, the respective cutouts **72-78b** include at least one inclined portion extended parallel to the cutouts **91-97b** of the pixel electrode **191**.

The lower and upper cutouts **75c-78b** include an inclined portion extended from the right side of the pixel electrode **191** toward the lower or the upper side thereof, and horizontal and vertical portions extended from the respective ends of the inclined portion along the sides of the pixel electrode **190** while being overlapped with those sides and obtuse-angled against the inclined portion.

The first middle cutout **71** has a vertical portion extended along the left side of the pixel electrode **191** while being overlapped therewith, and a horizontal portion extended from the center of the vertical portion along the storage electrode line **131a**. The second and third middle cutouts **72** and **73a** have a horizontal portion extended along the storage electrode line **131a**, a pair of inclined portions extended from the horizontal portion toward the left side of the pixel electrode **191** oblique to the storage electrode line **131a**, and vertical end portions extended from the ends of the inclined portions along the left side of the pixel electrode **191** while being overlapped with the left side and obtuse-angled against the inclined portions. The fourth middle cutout **74a** has a vertical portion extended along the right side of the pixel electrode **191** while being overlapped therewith, a pair of inclined portions extended from the respective ends of the vertical portion toward the left side of the pixel electrode **191**, and vertical end portions extended from the ends of the inclined portions along the left side of the second sub-pixel electrode **191b** while being overlapped with the left side and obtuse-angled against the inclined portions.

Triangle-shaped notches are formed at the inclined portions of the cutouts **72-77b**. The notches may be formed in the shape of a rectangle, a trapezoid, or a semi-circle, or they may be concave or convex.

An alignment layer **21** is formed on the common electrode **270** and on the overcoat layer **250** to align the liquid crystal layer **3**.

Polarizers **12** and **22** are attached to the outer surfaces of the panels **101** and **201**.

The display operation of the LCD according to the present embodiment is substantially the same as that related to the previous embodiment, and a further detailed explanation thereof would be redundant and thus will be omitted.

Even with the LCD according to the second embodiment, the magnitudes of the kickback voltages V_{kc} and V_{kd} of the first and second sub-pixels PX_c and PX_d may be adjusted to be substantially the same. The capacitance values of the liquid crystal capacitors C_{LCc} and C_{LCd} of the first and second sub-pixels PX_c and PX_d are determined depending upon the area ratio of the first sub-pixel electrode **191a** to the second sub-pixel electrode **191b**, and the parasitic capacitances C_{gdc} and C_{gdd} are also determined depending upon the design factors. Accordingly, the areas of the first and second drain electrodes **175a** and **175b** overlapped with the storage electrodes **133a** and **133b** are suitably controlled to produce the capacitance values of the first and second storage capacitors C_{STc} and C_{STd} that are capable of making the magnitudes of the kickback voltages V_{kc} and V_{kd} the same. In this way, the magnitudes of the kickback voltages V_{kc} and V_{kd} of the first and second sub-pixels PX_c and PX_d are controlled to be the same, thereby preventing the display screen from flickering.

Furthermore, the area of the second sub-pixel electrode **191b** that receives a relatively high voltage is established to be smaller than the area of the first sub-pixel electrode **191a**, thereby reducing the deformation in the lateral side gamma curve. For example, the area ratio of the first sub-pixel electrode **191a** to the second sub-pixel electrode **191b** may be established to be about 2:1, thereby enhancing the lateral side visibility.

Many features of the LCD shown in FIGS. 1 to 8 are also features of the LCD shown in FIGS. 9 to 12.

A pixel PX in an LCD according to the third embodiment of the present invention will now be specifically described with reference to FIG. 13.

FIG. 13 is an equivalent circuit diagram of a pixel PX in a pixel array of an LCD according to a third embodiment of the present invention.

FIG. 13 illustrates display signal lines (GL , DL , SLa , SLb) and an equivalent circuit of two sub-pixels of one pixel PX . The display signal lines include a gate line indicated by GL , a data line indicated by DL , and a pair of first and second storage electrode lines SLa and SLb proceeding substantially parallel to the gate line GL .

The respective pixels PX include a pair of sub-pixels PX_e and PX_f . The sub-pixels PX_e and PX_f respectively include switching elements Q_e and Q_f connected to the gate and the data lines GL and DL , liquid crystal capacitors C_{LCe} and C_{LCf} connected to those switching elements, and storage capacitors C_{STe} and C_{STf} connected to the switching elements Q_e and Q_f and the storage electrode lines SLa and SLb .

The first and second storage electrode lines SLa and SLb receive first and second common voltages V_{com1} and V_{com2} . The first and second common voltages V_{com1} and V_{com2} swing between the high voltage and the low voltage with a phase difference of 180° . One data voltage is applied to the respective sub-pixels PX_e and PX_f enabled by the gate signal, and is charged thereto. The pixel voltages charged at the sub-pixels PX_e and PX_f are converted into a high voltage and a low voltage (or a low voltage and a high voltage) in accordance with the first and second common voltages V_{com1} and V_{com2} applied to the respective storage electrode lines SLa and SLb , and are differentiated from each other. In this way, different pixel voltages are received by the sub-pixels PX_e and PX_f , thereby enhancing the lateral side visibility.

In embodiments having the structure according to the third embodiment, the magnitudes of the kickback voltages V_{ke} and V_{kf} of the first and second sub-pixels PX_e and PX_f are substantially the same. The capacitance values of the liquid crystal capacitors C_{LCe} and C_{LCf} of the first and second sub-

pixels PX_e and PX_f may be different from each other, and the parasitic capacitances C_{gde} and C_{gdf} may also be different from each other depending upon the design factors. Accordingly, the capacitance values of the first and second storage capacitors C_{STe} and C_{STf} may be suitably controlled to make the magnitudes of the kickback voltages V_{ke} and V_{kf} the same. In this way, the magnitudes of the kickback voltages V_{ke} and V_{kf} of the first and second sub-pixels PX_e and PX_f are controlled to be the same, thereby preventing the display screen from flickering.

According to various embodiments of the present invention, one pixel is divided into two sub-pixels, and different data voltages may be separately applied to (or evolved in) the two sub-pixels, thereby enhancing the lateral side visibility. Furthermore, the two sub-pixels may have different area sizes from each other, thereby reducing the deformation in the lateral side gamma curve. For example, the storage capacitances of the two sub-pixels may be designed to make the kickback voltages of each sub-pixel the same, thereby preventing the display image quality from being deteriorated such as by flickering.

While the present invention has been described in detail with reference to the preferred embodiments, those skilled in the art will appreciate that various modifications and substitutions can be made thereto without departing from the spirit and scope of the present invention as set forth in the appended claims.

What is claimed is:

1. A liquid crystal display comprising:

a plurality of pixels arranged in the form of a matrix, at least one of the pixels having first and second sub-pixels, wherein the first sub-pixel includes:

a first switching element;

a first liquid crystal capacitor connected to the first switching element; and

a first storage capacitor connected to the first switching element and the first liquid crystal capacitor,

wherein the second sub-pixel includes:

a second switching element;

a second liquid crystal capacitor connected to the second switching element; and

a second storage capacitor connected to the second switching element and the second liquid crystal capacitor,

wherein the first liquid crystal capacitor has greater capacitance than the second liquid crystal capacitor, and

wherein the first storage capacitor has greater capacitance than the second storage capacitor.

2. The liquid crystal display of claim 1, wherein the liquid crystal capacitor comprises:

a sub-pixel electrode connected to the switching element; a common electrode opposing the pixel electrode with a liquid crystal layer therebetween,

wherein the first sub-pixel electrode is greater than the second sub-pixel electrode, and the second sub-pixel electrode is applied higher voltage than the first sub-pixel electrode.

3. The liquid crystal display of claim 2, wherein the first switching element is a first thin film transistor and the second switching element is a second thin film transistor, and a channel width to channel length ratio of the first thin film transistor is greater than a channel width to channel length ratio of the second thin film transistor.

4. The liquid crystal display of claim 1, wherein the first switching element is a first thin film transistor and the second switching element is a second thin film transistor, and a chan-

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nel width to channel length ratio of the first thin film transistor is greater than a channel width to channel length ratio of the second thin film transistor.

5. A liquid crystal display comprising:

a plurality of pixels arranged in the form of a matrix, at least 5 one of the pixels having first and second sub-pixels, wherein the first sub-pixel includes:

a first thin film transistor comprising a first gate electrode, a first source electrode, and a first drain electrode;

a first sub-pixel electrode connected to the first drain elec- 10 trode;

a first storage electrode insulated from the first thin film transistor and the first sub-pixel electrode,

wherein the second sub-pixel includes:

a second thin film transistor comprising a second gate 15 electrode, a second source electrode, and a second drain electrode;

a second sub-pixel electrode connected to the second drain electrode;

a second storage electrode insulated from the second thin 20 film transistor and the second sub-pixel electrode,

wherein the first sub-pixel electrode is greater than the second sub-pixel electrode, and

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wherein the first drain electrode overlaps the first storage electrode with an insulating layer therebetween, and the second drain electrode overlaps the second storage elec- trode with the insulating layer therebetween, and

the overlapping area between the first drain electrode and the first storage electrode is larger than the overlapping area between the second drain electrode and the second storage electrode.

6. The liquid crystal display of claim 5, wherein a channel width to channel length ratio of the first thin film transistor is greater than a channel width to channel length ratio of the second thin film transistor.

7. The liquid crystal display of claim 6, wherein the second sub-pixel electrode is applied higher voltage than the first sub-pixel electrode.

8. The liquid crystal display of claim 5, wherein the first and the second gate electrodes are connected to a first gate line.

9. The liquid crystal display of claim 5, wherein the first and the second source electrodes are connected to a first data line.

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专利名称(译)	液晶显示器		
公开(公告)号	US7969396	公开(公告)日	2011-06-28
申请号	US12/878623	申请日	2010-09-09
[标]申请(专利权)人(译)	金东GYU		
申请(专利权)人(译)	金东GYU		
当前申请(专利权)人(译)	SAMSUNG ELECTRONICS CO. , LTD.		
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发明人	KIM, DONG-GYU		
IPC分类号	G09G3/36		
CPC分类号	G02F1/136213 G02F1/13624 G02F1/136277 H01L27/124 H01L27/13		
优先权	1020050030678 2005-04-13 KR		
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摘要(译)

液晶显示器包括像素阵列。每个像素被分成第一子像素和第二子像素，并且不同的数据电压被分别施加到（或演变）两个子像素，从而增强了侧面可视性。每个子像素包括与子像素的存储电极重叠的子像素电极（连接到子像素的开关元件的漏电极）。第一预定电压被施加到第一子像素，第二预定电压被施加到第二子像素，因此第一子像素电极可以接收低于第二子像素电极的电压的电压。第一子像素电极的面积可以大于第二子像素电极的面积。第一子像素的第一漏电极和存储电极之间的重叠区域可以大于第二子像素的漏电极和存储电极之间的重叠区域。因此，第一子像素的反冲电压可以与第二子像素的反冲电压基本相同。

